



Products Catalog

Fixed Resistors

- General purpose chip resistors type
- High precision type
- Current sensing type
- Small & High power type
- Anti-Sulfurated type
- High temperature type
- Array type / Resistor network





Fixed Resistors (Surface Mount Resistors) INDEX

Classification	Product item	Part No.	Page
I	Safety and Legal Matters to Be Observed / Matters to Be Observed	When Using This Product	1
General purpose	Thick film chip resistors	ERJ XG, 1G, 2G, 3G, 6G, ERJ 8G*, 14*, 12*, 12Z*, 1T*	5
chip resistors	Precision thick film chip resistors	ERJ XG, 1G, 1R, 2R, 3R, 6R, 3E, 6E, 8E*, ERJ 14*, 12*, 1T*	8
	Thin film chip resistors, High voltage type	ERA 8P	12
High	Thin film chip resistors, High stability and reliability type	ERA 2V, 3V, 3K, 6V, 6K, 8V, 8K	14
precision	Metal film (Thin film) Chip resistors, High reliability type	ERA 1A, 2A, 3A, 6A, 8A	17
	High precision thick film chip resistors	ERJ PB3, PB6	20
	Thick film chip resistors / Low resistance type	ERJ 2LW, 3LW, 6LW, ERJ 2BW, 3BW, 6BW, 8BW, 6CW, 8CW ERJ 2BS/Q, 3BS/Q, 6DS/Q, 6BS/Q, 8BS/Q, 14BS/Q ERJ 3RS/Q, 6RS/Q, 8RS/Q, 14RS/Q, 12RS/Q, 12ZS/ Q, 1TRS/Q ERJ L03, L06, L08, L14, L12, L1D	22
Current sensing	Current sensing resistors, Metal plate type	ERJ MS4S*, MS4H*, MB1S*	28
	High power chip resistors / Wide terminal type	ERJ A1, B1, B2, B3	32
-	Low TCR high power chip resistors / Wide terminal type	ERJ D1, D2	37
	Anti-Surge thick film chip resistors	ERJ PA2, P03, PA3, P06, P08, PM8, P14	40
Small & High power	Anti-Surge thick film chip resistors (Double-sided resistive elements structure)	ERJ P6W*	45
-	Anti-Pulse thick film chip resistors	ERJ T06, T08, T14	47
	Anti-Sulfurated thick film chip resistors	ERJ S02, S03, S06, S08, S14, S12, S1D, S1T, ERJ U0X, U01, U02, U03, U06, U08, U14, U12, ERJ U1D, ERJ U1T, ERJ U6S, U6Q	50
Anti-Sulfurated	Anti-Sulfurated thick film chip resistors / Precision type	ERJ U2R, U3R, U6R	54
	Anti-Sulfurated thick film chip resistors / Anti-Surge type	ERJ UP3, UP6, UP8	56
-	Anti-Sulfurated thick film chip resistors / Wide terminal type	ERJ C1	59
High temperature	High temperature thick film chip resistors (Automotive Grade)	ERJ H2G, H2C, H2R, H3G, H3E, H3Q, H6G, HP6	62
	Chip resistor array	EXB 14V, 18V, 24V, 28V, N8V, 2HV, 34V, V4V, 38V, V8V, S8V	65
Resistor	Anti-Sulfurated chip resistor array	EXB U14, U18, U24, U28, U2H, U34, U38	69
network/Array	Chip resistor networks	EXB D, E, A, Q	72
-	Chip attenuator	EXB 14AT, 24AT	76
	Packaging methods (Ta	aping)	78
Common	Recommended land pa	attern	83
specifications	Recommended soldering c	onditions	86
	Standard for resistance value and re	sistance tolerance	87

*Not Recommended for New Design

Safety and Legal Matters to Be Observed

Product specifications and applications

- Please be advised that this product and product specifications are subject to change without notice for improvement purposes. Therefore, please request and confirm the latest delivery specifications that explain the specifications in detail before the final design, or purchase or use of the product, regardless of the application. In addition, do not use this product in any way that deviates from the contents of the company's delivery specifications.
- Unless otherwise specified in this catalog or the product specifications, this product is intended for use in general electronic equipment (AV products, home appliances, commercial equipment, office equipment, information and communication equipment, etc.).

When this product is used for the following special cases, the specification document suited to each application shall be signed/sealed (with Panasonic Industry and the user) in advance. These include applications requiring special quality and reliability, wherein their failures or malfunctions may directly threaten human life or cause harm to the human body (e.g.: space/aircraft equipment, transportation/traffic equipment, combustion equipment, medical equipment, disaster prevention/crime prevention equipment, safety equipment, etc.).

Safety design and product evaluation

- Please ensure safety through protection circuits, redundant circuits, etc., in the customer's system design so that a defect in our company's product will not endanger human life or cause other serious damage.
- This catalog shows the quality and performance of individual parts. The durability of parts varies depending on the usage environment and conditions. Therefore, please ensure to evaluate and confirm the state of each part after it has been mounted in your product in the actual operating environment before use. If you have any doubts about the safety of this product, then please notify us immediately, and be sure to conduct a technical review including the above protection circuits and redundant circuits at your company.

Laws / Regulations / Intellectual property

- The transportation of dangerous goods as designated by UN numbers, UN classifications, etc., does not apply to this product. In addition, when exporting products, product specifications, and technical information described in this catalog, please comply with the laws and regulations of the countries to which the products are exported, especially those concerning security export control.
- Each model of this product complies with the RoHS Directive (Restriction of the use of hazardous substances in electrical and electronic equipment) (2011/65/EU and (EU) 2015/863). The date of compliance with the RoHS Directive and REACH Regulation varies depending on the product model. Further, if you are using product models in stock and are not sure whether or not they comply with the RoHS Directive or REACH Regulation, please contact us by selecting "Sales Inquiry" from the inquiry form.
- During the manufacturing process of this product and any of its components and materials to be used, Panasonic Industry does not intentionally use ozone-depleting substances stipulated in the Montreal Protocol and specific bromine-based flame retardants such as PBBs (Poly-Brominated Biphenyls) / PBDEs (Poly-Brominated Diphenyl Ethers). In addition, the materials used in this product are all listed as existing chemical substances based on the Act on the Regulation of Manufacture and Evaluation of Chemical Substances.
- With regard to the disposal of this product, please confirm the disposal method in each country and region where it is incorporated into your company's product and used.
- The technical information contained in this catalog is intended to show only typical operation and application circuit examples of this product. This catalog does not guarantee that such information does not infringe upon the intellectual property rights of Panasonic Industry or any third party, nor imply that the license of such rights has been granted.
- Design, materials, or process related to technical owned by Panasonic Industry are subject to change without notice.

Panasonic Industry will assume no liability whatsoever if the use of our company's products deviates from the contents of this catalog or does not comply with the precautions. Please be advised of these restrictions.

Matters to Be Observed When Using This Product

(Fixed resistor)

Use environments and cleaning conditions

- This product (fixed resistor) is not designed for use in specific environments. Using the resistor in the following specific environments or service conditions may affect the performance/reliability of the resistor. Avoid using it in such specific environments. If you intend to use the resistor in such environments, checking the performance, reliability, etc., of the product sufficiently is your own responsibility.
 - (1) Used in liquid, such as water, oil, chemicals, and organic solvents.
 - (2) Used in a place exposed to direct sunlight, an outdoor place with no shielding, or a dusty place.
 - (3) Used in a place where the product is heavily exposed to sea breeze or a corrosive gas, such as Cl₂, H₂S, NH₃, SO₂, or NO_x.
 - (4) Used in an environment where static electricity and electromagnetic waves are strong.
 - (5) Located close to a heating component or a flammable material, such as a vinyl cable placed near the product.
 - (6) Sealed or coated with a resin.
 - (7) Solder flux of the resistor soldered with no-clean type solder, etc., is cleansed with a solvent, water, or a water-soluble cleaner, etc. (Water-soluble flux residues have a particularly large influence on a resistor.)
 - (8) Used in a place where dew concentrates on the product.
 - (9) Used in a contaminated state.

(Example: Touching the resistor mounted on a printed board leaving sebum on the resistor (improper handling))

- Sealing the resistor with a resin in a resin potting process, damp-proofing process, etc., applies excessive stress to the resistor, which may cause the internal electrodes a connection problem. In such cases, the proper operation of the resistor is not guaranteed. If you intend to use the resistor in such environments, checking the performance, reliability, etc., of the product sufficiently is your own responsibility.
- Do not leave the resistor immersed in a solvent for a long time. When using the resistor immersed in a solvent, confirm the operation of the product mounted on the board.
- When a cleaning solution or cleaning condition for cleaning the printed board or a drying condition for drying the printed board after soldering the resistor is improper, it may have a negative effect on the performance/reliability of the resistor. Confirming these conditions sufficiently is your own responsibility. Also examine the effects of soiled cleaning agent, cleaning residues, and post-cleaning contaminations, and control for these effects properly.

Response to anomalies and handling conditions

When the resistor is heating abnormally or emitting a smell, stop using the resistor immediately, for example, turn off the main power supply of the device.

Also, keep your face and hands away from the product as it may become hot and cause burns.

- The resistor is so thin that it may break easily when subjected to impact. Before putting the resistor in use, confirm that the resistor has not been broken by impact that applied thereto when mounted on the printed board. Applying impact to the resistor or pinching the resistor with a hard tool (pliers, tweezers, etc.) may chip the resistor or its protective film, which affects its performance. Be careful to avoid such cases.
- Do not reuse a resistor having been used on a printed board and removed therefrom. Do not touch the resistor with your bare hands.
- Be careful not to drop the resistor on the floor, etc. The resistor is likely to suffer mechanical or electrical damage when dropped on the floor. Avoid using said resistor.
- The resistor may have its resistance value changed due to electrostatic discharge (ESD). Take ESD prevention measures when handling the resistor. ESD prevention measures include an environment where static electricity is not likely to be generated (recommended RH: 40% to 60%), by wearing an earth band, conductive gloves, etc., grounding the device in which the resistor is incorporated, and placing a conductive mat, etc., on a work platform.
- It is guaranteed that a resistor not exposed to any stress will have its proper resistance value. Any stress or pressure applied to the resistor may cause its resistance value to change. Examine and evaluate the characteristics of the resistor sufficiently before using it.

Reliability and product life

A product conforming to "AEC-Q200" refers to a product having passed some or all of the evaluation test items defined in AEC-Q200. To know the detailed specifications of individual products or specific evaluation test scores, please contact us. We issue a delivery specification sheet for each product ordered. Please confirm with the sheet when you place an order with us.

Circuit design and circuit board design

- To prevent a case where a transient load (e.g., a pulse for a short period) too large for the product to handle is applied, make sure to evaluate and confirm the operation of the product incorporated in your product. Applying power or voltage (current) larger than the rated power or rated voltage (current) to the resistor may impair its performance and reliability. Make sure to use the resistor with power or voltage (current) equal to or lower than the rated power or rated voltage (current). The product warranty does not cover usage where an excessively large load, such as a pulse current, is applied to the product.
- The resistor may have a high temperature even when used with power equal to or lower than the rated power. Be careful in such cases. Another factor to be considered are effects on the board, peripheral components, etc., and the effects of peripheral components on the resistor. Make sure to confirm first that the temperature of the resistor incorporated in your product is equal to or lower than the specified temperature, and then use the resistor.
- When the resistors are connected in series or parallel, loads applied respectively to the resistors may not be equal to each other. Check whether the loads are equal in the actual circuit in which the resistors are incorporated.
- When a resistor is used in a high-frequency circuit, the resistor may fail to offer the required characteristics. Check whether the resistor offers the required characteristics in the actual circuit in which the resistors are incorporated.
- Be careful that unusual stress caused by an excessive bend of the printed board is not applied to the resistor. Design the circuit structure such that the resistor is not close to a perforated line for board splitting or on a line with sizable holes bored on the board.
- When a different component is mounted on the board where the resistor has been soldered, be careful that the board does not bend excessively. If necessary, provide the board with backup pins (support pins) to keep it straight.
- Avoid manual board splitting. Use a jig, etc., to break the board so that it does not bend excessively when split apart.

Mounting conditions

- When the product is used under mounting conditions departing from mounting conditions specified in our specification sheet, the product may be exposed to unexpected stress to fail. Be careful to avoid such a case. When mounting the resistor on a printed board, set the resistor's front and back surfaces in the direction indicated by the tape. Make sure to evaluate and confirm the operation of the resistor incorporated in your product and determine whether the resistor is usable as a component of the product.
- Set soldering conditions for the resistor within the recommended soldering conditions specified by our company. Any time, soldering condition departing from the specified soldering condition, such as a high peak temperature or a long heating may impair the performance/reliability of the resistor. Note that the specified soldering conditions indicate conditions under which degradation of the resistor characteristics does not occur but do not indicate conditions under which stable soldering can be performed. Check and set individual conditions under which stable soldering can be performed.
- Heat the resistor in advance so that a difference between the soldering temperature and the temperature of the resistor surface is reduced to 100 °C or lower. When dipping the soldered resistor in a solvent, etc., to cool the resistor rapidly, ensure that the temperature difference between the resistor and the solvent is 100 °C or lower during the dipping.
- When soldering the resistor using a soldering iron, apply hot air, etc., to the resistor to heat it sufficiently in advance and then solder the resistor without bringing the soldering iron tip into contact with the product. If the temperature of the soldering iron tip is high, finish the soldering work quickly (within 3 seconds when the temperature of the soldering iron tip is 350 °C or lower). In the case of a fixed resistor with low resistance, the resistor may fail to offer the exactly intended resistance value because of the variation in the solder volume, etc. Make sure to confirm the resistance value of the resistor in the actual circuit configuration.

- Soldering the resistor with too much solder or too little solder results in the poor reliability of the solder connection of the resistor. Use the proper volume of solder in the soldering process. Sufficiently check for the volume of solder used.
- Soldering with high bond strength or special property solder may affect the quality of the resistor. Do not use such solder.
- Use rosin-based solder flux. When using highly active solder flux made mainly of halogen (chlorine, bromine, etc.), flux residues may affect the performance and reliability of the resistor. Check the effects of flux residues before using the solder flux. Do not use highly acidic flux, water-soluble flux, or flux containing fluoride ions. When solder flux sticks to the resistor after the soldering process, the activation energy of the flux may corrode the resistor and cause it to fail. Prevent solder flux from sticking to the resistor.

Storage conditions

Keeping the product in the following environments or conditions may lead to degradation of its performance, solderability, etc. Do not keep the product in the following environments.

- (1) Stored in a place where the product is heavily exposed to sea breeze or a corrosive gas, such as Cl₂, H₂S, NH₃, SO₂, or NO_X.
- (2) Stored in a place where the product is exposed to direct sunlight.
- (3) Stored in a place where a temperature condition of 5 °C to 35 °C and a relative humidity condition of 45% to 85% cannot be maintained.
- (4) Kept in storage for more than one year from the delivery date (when the product is kept in conditions excluding any of the environments (1) to (3)).

Reference information

Guidelines

Before using the resistor, refer to the technical report issued by JEITA, EIAJ RCR-2121B "Safety Application Guide for Fixed Resistor for Use in Electronic Equipment" revised in February 2015.

Panasor

INDUSTRY

Thick Film Chip Resistors ERJ type ERJ XG, 1G, 2G, 3G, 6G series ERJ 8G, 14, 12, 12Z, 1T series

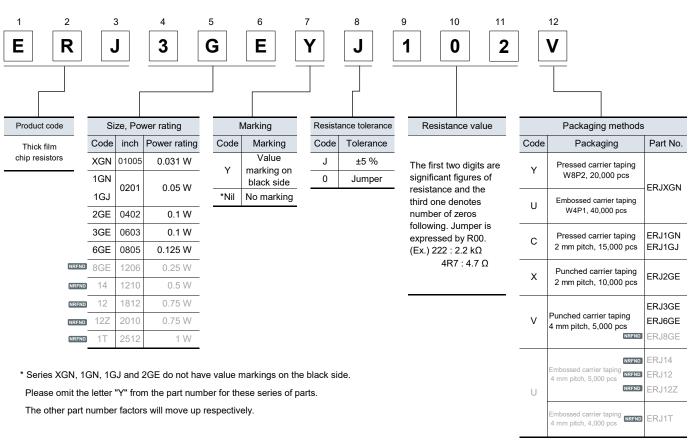
Features

- Small size and lightweight
- : Metal glaze thick film resistive element and three layers of electrodes High reliability
- Compatible with placement machines : Taping packaging available
- Suitable for both reflow and flow soldering
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJXG, ERJ1GN)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

ERJ XGN, 1GN, 1GJ, 2GE, 3GE, 6GE, 8GE, 14, 12, 12Z, 1T series, ±5 %



* For the automotive application, please use ERJ1GJ as 0201 inch size from the new design.

Not recommended for new design





(Oct. 2021) Products marked as "NRFND" are not recommended for new design Target products : ERJ8G, 14, 12, 12Z, 1T series Please refer to the recommended alternatives with "Design Support Tool"

Thick Film Chip Resistors

Ratings

[For Resistor]

Part No. (inch size)	Rated power ^{*1} (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resis ran (Ω	ge	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJXG (01005)	0.031	15	30	±5	1 to 1 M	(E24)	R<10Ω : −100 to +600 10Ω to 100Ω : ±300 100Ω≤R : ±200		-
ERJ1GN (0201)	0.05	25	50	±5	1 to 10 M	(E24)		-55 to +125	
ERJ1GJ (0201)	0.05	25	50	±5	1 to 10 M	(E24)	R<10 Ω : –100 to +600		Grade 1
ERJ2G (0402)	0.1	50	100	±5	1 to 10 M	(E24)	10 Ω to 1 M Ω : ±200		
ERJ3G (0603)	0.1	75	150	±5	1 to 10 M	(E24)	1 MΩ <r +150<="" :="" td="" to="" –400=""><td>-55 to +155</td><td>Grade 0</td></r>	-55 to +155	Grade 0
ERJ6G (0805)	0.125	150	200	±5	1 to 10 M	(E24)			
ERJ8G (1206)	0.25	200	400	±5	1 to 10 M	(E24)			
ERJ14 (1210)	0.5	200	400	±5	1 to 10 M	(E24)	R<10 Ω : -100 to +600		
ERJ12 (1812)	0.75	200	500	±5	1 to 10 M	(E24)	10 Ω to 1 M Ω : ±200	-55 to +155	Grade 0
ERJ12Z (2010)	0.75	200	500	±5	1 to 10 M	(E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td></td><td></td></r>		
ERJ1T (2512)	1	200	500	±5	1 to 1 M	(E24)			

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\/Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

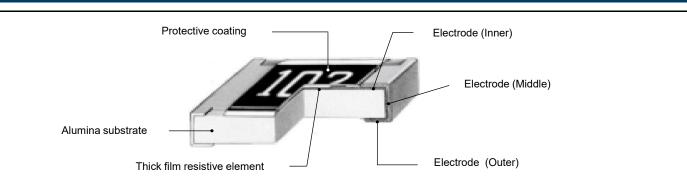
*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

	LEOI JUII			
	Part No.	Resistance(Ω)	Rated current(A)	Maximum overload current (A) ^{*1}
	ERJXG		0.5	1
	ERJ1G		0.5	I
	ERJ2G	$50\ m\Omega$ or less	1	2
	ERJ3G		I	2
	ERJ6G		2	4
NR	™ ERJ8G			
NR	ERJ14			
NRI	ERJ12	$50\ m\Omega$ or less	2	4
NR	fnd ERJ12Z			
NR	ERJ1T			

[For Jumper]

* 1 :Overload test current

Construction

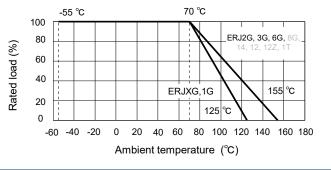


Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

NRFND Not recommended for new design

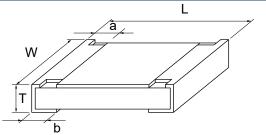
above 70 ℃, power rating shall be derated in accordance with the figure below.

Power derating curve



Thick Film Chip Resistors

Dimensions (not to scale)



						Unit : mm			
Part No.		Dimensions							
Fait NO.	L	W	а	b	Т	(Reference) (g/1000 pcs)			
ERJXG	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04			
ERJ1G	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15			
ERJ2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8			
ERJ3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJ6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4			
NREND ERJ8G	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10			
(NRFND) ERJ14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16			
NREND ERJ12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27			
NREND ERJ12Z	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27			
NREND ERJ1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45			

Not recommended for new design

Performance

Test item	Performance re	quirements ⊿R	Test conditions	
rescilent	Resistor type Jumper type			
Resistance	Within specified tolerance	50 m Ω or less	20 °C	
T. C. R.	Within specified T. C. R.	50 m Ω or less	+25℃ / +155℃ (ERJXG,1G : +25℃ / +125℃)	
Overload	+2 %	50 m Ω or less	Rated voltage× 2.5, 5 s	
Oventoad	±2 /0	50 m22 of less	Jumper type : Max. overload current, 5 s	
Resistance to soldering heat	±1 %	50 m Ω or less	270 ℃, 10 s	
Rapid change of	+1 %	50 mO or less	–55 ℃ (30 min.) / +155 ℃ (ERJXG,1G : +125 ℃)	
temperature	±1 70	50 m22 of less	(30 min.), 100 cycles	
High temperature exposure	±1 %	50 m Ω or less	+155℃ (ERJXG,1G : +125℃), 1000 h	
Damp heat, Steady state	±1 %	50 m Ω or less	60 ℃, 90 % to 95 %RH, 1000 h	
			60 ℃, 90 % to 95 %RH,	
Load life in humidity	±3 %	50 m Ω or less	Rated voltage (Jumper type :Rated current),	
			1.5 h ON / 0.5 h OFF cycle, 1000 h	
Endurance at 70℃	+3 %	50 m Ω or less	70℃, Rated voltage (Jumper type : Rated current),	
Endurance at 70 C	IO 70	SU TILIZ OF IESS	1.5 h ON / 0.5 h OFF cycle, 1000 h	

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

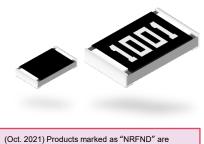
Panasonic

INDUSTRY

Precision Thick Film Chip Resistors

ERJ type

- ERJ XG, 1G series
- ERJ 1R, 2R, 3R, 6R series
- ERJ 3E, 6E, 8E, 14, 12, 1T series





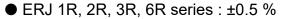
(Oct. 2021) Products marked as "NRFND" are not recommended for new design. Target products : ERJ8E, 14, 12, 1Tseries Please refer to the recommended alternatives with "Design Support Tool".

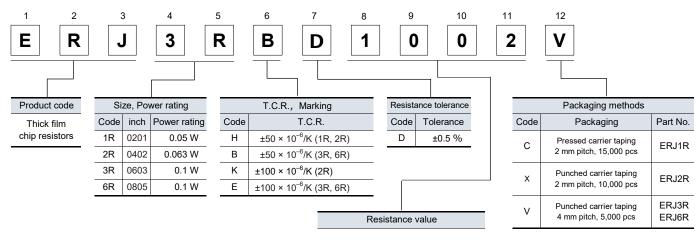
Features

- Small size and lightweight
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Compatible with placement machines : Taping packaging available
- Suitable for both reflow and flow soldering
- Low resistance tolerance : ERJXG, 1G, 2R, 3E, 6E, 8E, 14, 12, 1⊤ series : ±1 % ERJ1R, 2R, 3R, 6R series : ±0.5 %
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJ1R, ERJXG, ERJ1GN)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.





The first three digits are significant figures of resistance and the last one denotes number of zeros following. Example : $1002 \rightarrow 10 \text{ K}\Omega$

Precision Thick Film Chip Resistors

xplanation	otp	bart n	umbers							
		Note	: Please chec	k the "I	Ratings" for	the presence/absence	ce of part numbe	rs for c	ombinations of the s	symbols b
ERJ XGN,	1GN	I, 1G	J, 2RC, 2I	RK , 3	BEK, 6E	N, 8EN, 14N,	12N, 12S,	1TN	series : ±1 %	
1 2		3	4 5		6	7 8	9 10	11	12	
ER	•		8 E		N	F 1	0 0	2		
		Г]				
Product code	S	Size, Pow	er rating	Resista	ance tolerance	Resistance	e value		Packaging methods	5
Thick film	Code	inch	Power rating	Code	Tolerance			Code	Packaging	Part No.
chip resistors	XGN	01005	0.031 W	F	±1 %	The first three digits	U	Y	Pressed carrier taping	
	1GN	0201	0.05 W			figures of resistance one denotes number			W8P2, 20,000 pcs	ERJXGN
	1GJ					following.		U	Embossed carrier taping	
	2RC	0402	0.1 W			Decimal point is exp	,		W4P1, 40,000 pcs	
	2RK	0402	0.1 W			Example : $1002 \rightarrow 1$	10 KΩ	С	Pressed carrier taping 2 mm pitch, 15,000 pcs	ERJ1GN ERJ1GJ
	3EK 6EN	0603 0805	0.1 W							
NRFND	8EN	1206	0.125 W					Х	Punched carrier taping 2 mm pitch, 10,000 pcs	ERJ2RC ERJ2RK
NRFND	14N	1200	0.25 W						, , ,,,,,,	
NRFND	12N	1812	0.75 W					V	Punched carrier taping	ERJ3EK ERJ6EN
NRFND	12S	2010	0.75 W					•	4 mm pitch, 5,000 pcs	ERJ8EN
NRFND	1TN	2512	1 W							ED MAN
	1		<u>.</u>				NRFNE	U	Embossed carrier taping 4 mm pitch, 5,000 pcs	ERJ14N ERJ12N ERJ12S
* For the	automo	tive appli	cation, please us	e ERJ1(GJ as 0201 in	ch size from the new des	sign.		Embossed carrier taping 4 mm pitch, 4,000 pcs	ERJ1TN

NRFND Not recommended for new design

Ratings

<+0.5 %>

\10.5 /d									
Part No. (inch size)	Rated power ^{*1} (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resist ran (Ω	ge	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJ1RH (0201)	0.05	15	30	±0.5	1 k to 1 M	(E24,E96)	±50	-55 to +125	-
ERJ2RH (0402)	0.063	50	100	±0.5	100 to 100 k	(E24,E96)	±50		
ERJ2RK (0402)	0.063	50	100	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100		
ERJ3RB (0603)	0.1	75	150	±0.5	100 to 100 k	(E24,E96)	±50	-55 to +155	Grade 0
ERJ3RE (0603)	0.1	75	150	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100	-55 10 + 155	Grade 0
ERJ6RB (0805)	0.1	150	200	±0.5	100 to 100 k	(E24,E96)	±50		
ERJ6RE (0805)	0.1	150	200	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100		

*1 : Use it on the condition that the case temperature is below the upper category temperature.

*2 : Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or limiting element voltage listed above, whichever less.

*3 : Overload test voltage (OTV) shall be determined from OTV = specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change managements and set of the set of t

Precision Thick Film Chip Resistors

Ratings

Part No. (inch size)	Power rating ^{*1} (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	rai	stance nge Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJXGN (01005)	0.031	15	30	±1	10 to 1 M ^{*4}	(E24,E96)	$R < 100 \Omega : \pm 300$ 100 Ω ≤ R : ±200		
ERJ1GN (0201)	0.05	25	50	±1	10 to 1 M ^{*4}	(E24,E96)	±200	-55 to +125	-
ERJ1GJ (0201)	0.05	25	50	±1	10 to 1 M ^{*4}	(E24,E96)	1200		Grade 1
ERJ2RC (0402)	0.1	50	100	±1	1 to 9.76	(E24,E96)	-100 to +600		
ERJ2RK (0402)	0.1	50	100	±1	10 to 1 M	(E24,E96)		-55 to +155	Grade 0
ERJ3EK (0603)	0.1	75	150	±1	10 to 1 M	(E24,E96)	±100	-55 10 + 155	Glade
ERJ6EN (0805)	0.125	150	200	±1	10 to 2.2 M	(E24,E96)			
ERJ8EN (1206)	0.25	200	400	±1	10 to 2.2 M	(E24,E96)			
ERJ14N (1210)	0.5	200	400	±1	10 to 1 M	(E24,E96)			
ERJ12N (1812)	0.75	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ12S (2010)	0.75	200	500	±1	10 to 1 M	(E24,E96)			
ERJ1TN (2512)	1	200	500	±1	10 to 1 M	(E24,E96)			

*1 : Use it on the condition that the case temperature is below the upper category temperature.

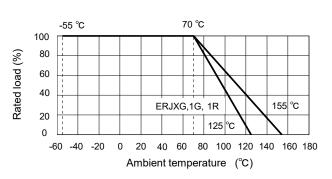
*2 : Rated continuous working voltage (RCWV) shall be determined from RCWV= / Power rating × Resistance value, or limiting element voltage listed above, whichever less.

*3 : Overload test voltage (OTV) shall be determined from OTV = specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.

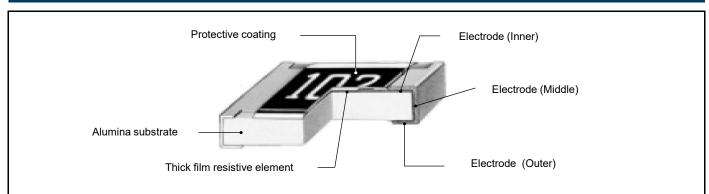
*4 : Please contact us when you need a type with a resistance of less than 10 Ω .

Power derating curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction

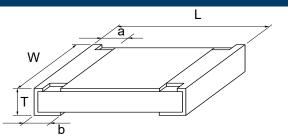


Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change mutual nearest in the second state of the second stat

NRFND Not recommended for new design

Precision Thick Film Chip Resistors

Dimensions (not to scale)



Dort No.		Dimensions (mm)									
Part No.	L	W	а	b	Т	(Reference) (g/1000 pcs)					
ERJXG	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04					
ERJ1G	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15					
ERJ1R	0.00±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.2310.03	0.15					
ERJ2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8					
ERJ3R	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2					
ERJ3E	1.00±0.15	0.0010.13/-0.03	0.30±0.20	0.00±0.10	0.4510.10	2					
ERJ6R	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4					
ERJ6E	2.00±0.20	1.25±0.10	0.40±0.20	0.4010.20	0.0010.10	-					
NREND ERJ8EN	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10					
NRFND ERJ14N	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16					
NREND ERJ12N	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27					
NREND ERJ12S	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27					
NREND ERJ1TN	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45					

Not recommended for new design

Performance

• ERJ 1R, 2R, 3R, 6R series : ±0.5 % (D)

Test item	Performance	Test conditions
	requirements ⊿R	
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	Rated voltage × 2.5, 5 s
Resistance to soldering heat	±1 %	270 °C, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (ERJ1R : +125 ℃)(30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃ (ERJ1R : +125 ℃), 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±2 %	60 ℃, 90 % to 95 %RH, Rated voltage,
Load me in indinidity	ERJ1R : ±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 $^\circ\!$	±2 % ERJ1R : ±3 %	70 $^\circ \!$

• ERJ XGN, 1GN, 1GJ, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN series : ±1 % (F)

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃ (ERJXG,ERJ1G : +25℃ / +125 ℃)
Overload	±2 %	Rated voltage × 2.5, 5 s
Resistance to soldering heat	±1 %	270 °C, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.)/+155 ℃ (ERJXG,ERJ1G : +125 ℃)(30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃ (ERJXG,ERJ1G : +125 ℃), 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±2 % ERJXG,1G : ±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±2 % ERJXG,1G : ±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

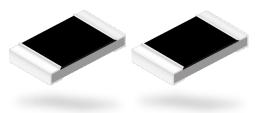
Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Should a safety concern arise regarding this product, please be sure to contact us immediately.

anasonic

INDUSTRY

Thin Film Chip Resistors, **High Voltage Type**



ERA P type

ERA 8P series

Features

- High voltage
- High reliability
- High accuracy
- High performance
- Anti-ESD
- (AEC-Q200-002 HBM Guarantee at 4 kV) : Original structure for sulfurated performance
- Anti-sulfurated Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C
- **RoHS** compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

: Stable at high temperature and humidity

: Original structure for high ESD performance

: Low current noise, excellent linearity

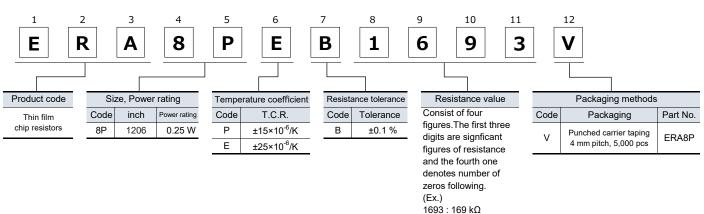
Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

: Achieves high limiting element voltage with original design concept (500V @ $1M\Omega$)

(85 \degree 85 %RH rated load, Category temperature range : -55 \degree to +155 \degree)

: Low resistance tolerance and temperature coefficient of resistance



Ratings Limiting Maximum Category Power rating Resistance T.C.R. Part No. element overload Part No. AEC-Q200 Resistance range*3 temperature at 85 ℃^{*1} tolerance voltage (inch size) voltage*2 (detail) (×10⁻⁶/K) (Ω) range Grade (W) (%) (°C) (V) (V) ERA8P ERA8PEB ±25 0.25 500 1000 ±0.1 160 k to 1 M (E24, E96) -55 to +155 Grade 0 (1206) ERA8PPB ±15

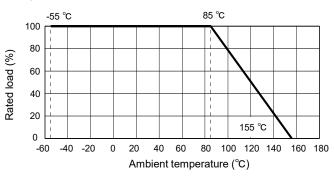
*1: Use it on the condition that the case temperature is below the upper category temperature

*2: Rated continuous working voltage (RCWV) shall be determined from RCWV= (Power Rating × Resistance Values), or limiting element voltage listed above, whichever less.

*3: E192 series resistance values are also available. The E192 series has custom part numbers. Please contact us for details.

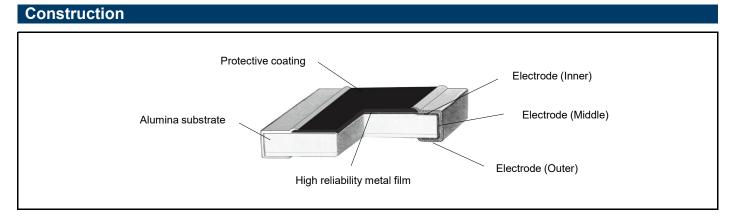
Power derating curve

For resistors operated in ambient temperatures above 85°C, power rating shall be derated in accordance with the figure on the right.

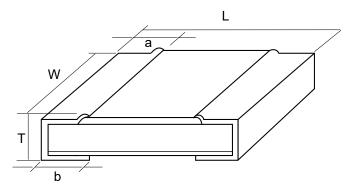


Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use Design and specifications are each subject to orange matched to contact us immediately. Should a safety concern arise regarding this product, please be sure to contact us immediately. 12

Thin Film Chip Resistors, High Voltage Type



Dimensions (not to scale)



						Unit : mm
Part No			Dimensions			Mass (Weight) (Reference)
Part No.	L	W	а	b	Т	(g/1000 pcs)
ERA8P	3.20±0.20	1.60±0.10	0.50±0.20	0.50±0.20	0.55±0.10	10

Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±0.1 %	Specified magnification (2.5) × RCWV or Maximum overload voltage, whichever less, 5 s
Resistance to soldering heat	±0.1 %	270 ℃, 10 s
Rapid change of temperature	±0.1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.),1000 cycles
High temperature exposure	±0.1 %	+155 ℃, 1000 h
Damp heat, Steady state	±0.1 %	85 ℃, 85 %RH, 1000 h
Load life in humidity	±0.1 %	85 ℃, 85 %RH, 10 % of Rated_power ^{*1} , 1.5 h ON / 0.5 h OFF cycle,1000 h
Endurance at 85℃	±0.1 %	85 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Electro static discharge (HBM)	±0.1 %	AEC-Q200-002 [:] 150 pF, 2000 Ω, positive 5 times, negative 5 times
5 (,		ERA8P : 4.0 kV (Class 3)

*1: Applied Voltage is " $\sqrt{0.1 \times \text{Power Rating} \times \text{Resistance Values}}$ ".

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to charge without notice, the subject to charge without notice, the subject to charge without notice to contact us immediately. Should a safety concern arise regarding this product, please be sure to contact us immediately. 13

'anasor

INDUSTRY

Thin Film Chip Resistors, **High Stability and Reliability Type** ERA V type

(High resistance value ERA K type)

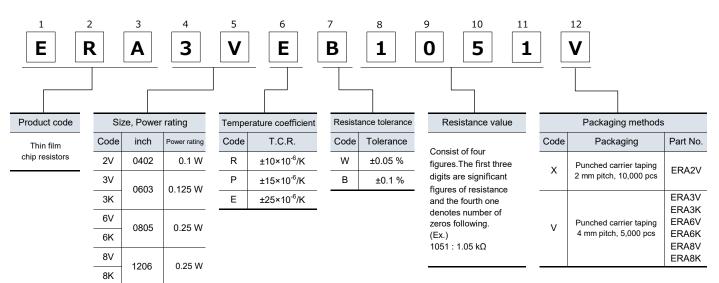
ERA 2V, 3V, 6V, 8V series (ERA 3K, 6K, 8K series)

Features

- : To realize higher power rating, Limiting element voltage, and maximum High Power overload voltage than current products : Stable at high temperature and humidity High reliability (85 °C 85 %RH rated load, Category temperature range : -55 °C to +155 °C) High accuracy : Low resistance tolerance and temperature coefficient of resistance High performance : Low current noise, excellent linearity Anti-ESD : Original structure for high ESD performance (AEC-Q200-002 HBM Class 1c and above) Anti-sulfurated : Original structure for sulfurated performance
- : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C Reference standard
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions. please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Thin Film Chip Resistors, High Stability and Reliability Type

Rating	S								
Part No. (inch size)	Power rating at 85 ℃ ^{*1} (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Part No. (detail)	Resistance tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Resistance range ^{*4} (Ω)	Category temperature range (℃)	AEC-Q200 Grade
				ERA2VEB	±0.1	±25	47 to 100 k ^{*5} (E24, E96)		
ERA2V	0.1	75	150	ERA2VPB	±0.1	±15			
(0402)	0.1	75	150	ERA2VRB	±0.1	±10	1 k to 47 k ^{*5} (E24, E96)		
				ERA2VRW	±0.05	10			
				ERA3VEB	±0.1	±25	47 to 100 k (E24, E96)		
ERA3V	0.125	100	200	ERA3VPB	±0.1	±15			
(0603)	0.125	200	ERA3VRB	±0.1	±10	1 k to 100 k (E24, E96)			
				ERA3VRW	±0.05	10		 	Grade 0
ERA3K (0603)	0.125	100	200	ERA3KEB	±0.1	±25	102 k to 240 k (E24, E96)		
				ERA6VEB	±0.1	±25	47 to 100 k (E24, E96)		
ERA6V	0.25	150	150 300	ERA6VPB	±0.1	±15			
(0805)	0.25	150	300	ERA6VRB	±0.1	±10	1 k to 100 k (E24, E96)		
				ERA6VRW	±0.05	ΞIU			
ERA6K (0805)	0.25	150	300	ERA6KEB	±0.1	±25	102 k to 750 k (E24, E96)		
				ERA8VEB		±25	47 to 100 k (E24, E96)		
ERA8V	0.25	200	400	ERA8VPB	±0.1	±15	1 k to 100 k (E24, E96)		
(1206)	0.25	200	400	ERA8VRB		±10	1 k to 100 k (E24, E96)		
				ERA8VRW	±0.05	±10	1 K to 100 K (L24, L90)		
				ERA8KEB		±25	102 k to 1 M (E24, E96)		
ERA8K	0.25	200	0 400	ERA8KPB	±0.1	±15	102 K (0 I M (L27, E90)	_	
(1206)	0.25	200	400	ERA8KRB		±10	102 k to 160 k (E24, E96)		
				ERA8KRW	±0.05	±10	102 K (0 100 K (L24, E90)		

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

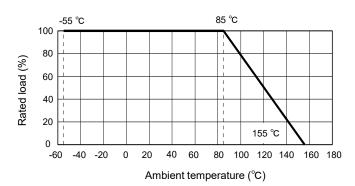
*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5) × RCWV or Maximum Overload Voltage listed above, whichever less.

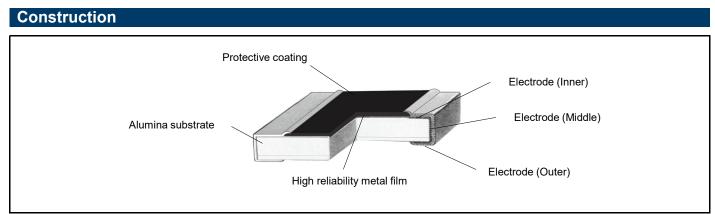
*4: E192 series resistance values are also available. The E192 series has custom part numbers. Please contact us for details.

*5: Expanded resistance range

Power derating curve

For resistors operated in ambient temperatures above 85°C, power rating shall be derated in accordance with the figure on the right.

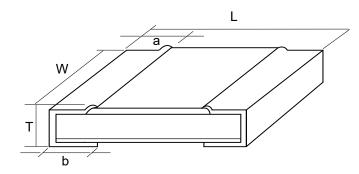




Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

Thin Film Chip Resistors, High Stability and Reliability Type

Dimensions (not to scale)



						Unit : mm
Part No.			Dimensions			Mass (Weight)
Fall NO.	L	W	а	b	Т	(Reference) (g/1000 pcs)
ERA2V	1.00±0.05	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.35±0.05	0.6
ERA3V,3K	1.60±0.15	0.80±0.10	0.30±0.20	0.30±0.20	0.45±0.10	2
ERA6V,6K	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.55±0.10	5
ERA8V,8K	3.20±0.20	1.60±0.10	0.50±0.20	0.50±0.20	0.55±0.10	10

Performance

Test Item	Performance	Test conditions
Resistance	requirements ⊿R Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±0.1 %	Rated voltage× 2.5, 5 s
Resistance to soldering heat	±0.1 %	270 ℃, 10 s
Rapid change of temperature	±0.1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.),1000 cycles
High temperature exposure	±0.1 %	+155 ℃, 1000 h
Damp heat, Steady state	±0.1 %	85 °C, 85 %RH, 1000 h
Load life in humidity	±0.1 %	85 ℃, 85 %RH, 10 % of Rated power ^{*1} , 1.5 h ON / 0.5 h OFF cycle , 1000 h
Endurance at 85℃	±0.1 %	85 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
		AEC-Q200-002 : 150 pF, 2000 Ω, positive 5 times, negative 5 times
Electro static	· • • • • • · *2	ERA2V : 1.0 kV (Class 1c)
discharge (HBM)	±0.1 % ^{*2}	ERA3V(3K):1.5 kV (Class 1c)
		ERA6V(6K) : 2.0 kV (Class 2)
		ERA8V(8K) : 2.0 kV (Class 2)

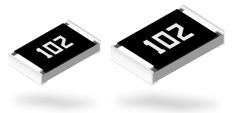
*1: Applied Voltage is " $\sqrt{0.1 \times \text{Power Rating} \times \text{Resistance Values}}$ ", or "Limiting Element Voltage×0.316", whichever less.

*2: Depends on resistance value.

Panasonic

INDUSTRY

Metal Film (Thin Film) Chip Resistors, High Reliability Type



ERA A type ERA 1A, 2A, 3A, 6A, 8A series

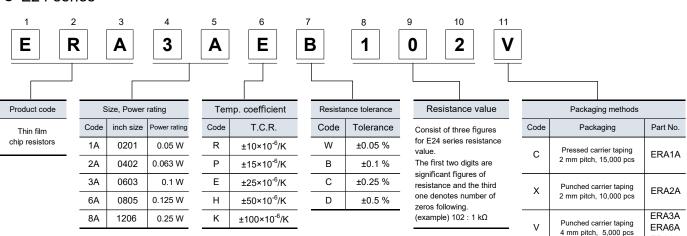
Features

- High reliability
- : Stable at high temperature and humidity
- (85 $^{\circ}$ C 85 $^{\circ}$ RH rated load, Category temperature range : –55 $^{\circ}$ C to +155 $^{\circ}$ C)
- : Low resistance tolerance and Temperature Coefficient of Resistance
- High accuracyHigh performance
- : Low current noise, excellent linearity : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C
- Reference standard
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

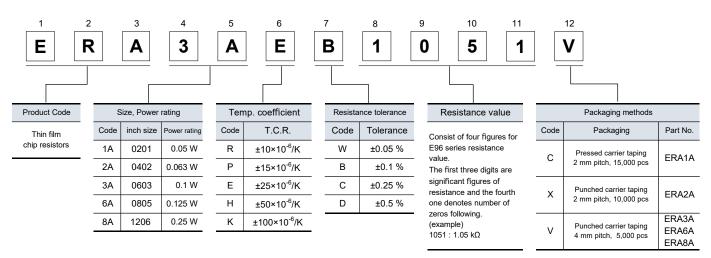
Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

E24 series



• E96 series and other Resistance values



Note : Duplicated resistance values as E24 series part umbers shall follow E24 part numbers. (apply three digit resistance value)

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately. ERA8A

Metal Film (Thin Film) Chip Resistors, High Reliability Type

Rating	S											
Part No. (inch size)	Power rating ^{*1} (85 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Part No. (detail)	Resistance tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Resista range (Ω)	*4 *5	Category temperature range (℃)	AEC-Q200 Grade		
ERA1A				ERA1AEB ERA1AEC	±0.1 ±0.25	±25	100 to 10 k	(E24,E96)				
(0201)	0.05	25	50	ERA1ARC ERA1ARB	±0.25 ±0.1	±10	100 to 10 k	(E24,E96)				
				ERA1ARW	±0.05		1 k to 10 k	(E24,E96)				
				ERA2AKD	±0.5	±100	10 to 46.4	(E24,E96)	-	One de 1		
55464				ERA2AED ERA2AEC	±0.5 ±0.25	±25	47 to 100 k	(E24,E96)		Grade 1		
ERA2A (0402) 0.063	50	100	ERA2AEB ERA2APC	±0.1 ±0.25	±15	200 to 47 k	(E24,E96)					
				ERA2APB ERA2ARC	±0.1 ±0.25	±10	200 to 47 k	(E24,E96)				
				ERA2ARB	±0.1				-	_		
			ERA3AHD	±0.5 ±0.5	±50	10 to 46.4	(E24,E96)	-				
			450	ERA3AED ERA3AEC	±0.25	±25	47 to 330 k	(E24,E96)	-55 to +155			
ERA3A				ERA3AEB	±0.1		470 to 100 k					
(0603)	0.1	75	150	ERA3APC	±0.25	±15		(E24,E96)				
				ERA3APB ERA3ARC	±0.1 ±0.25	±10						
				ERA3ARC ERA3ARB	±0.25 ±0.1		1 k to 100 k	(E24,E96)				
				ERA3ARW	±0.05		1 K to 100 K	(E24,E90)				
				ERA6AHD	±0.00	±50	10 to 46.4	(E24,E96)				
				ERA6AED	±0.5	200	10 10 10.1	(, ,				
				ERA6AEC	±0.25	±25	47 to 1 M	(E24,E96)				
				ERA6AEB	±0.1			. ,				
ERA6A (0805)	0.125	100	200	ERA6APC	±0.25	±15	470 to 100 k		-	Grade 0		
(0000)				ERA6APB	±0.1	113	470 to 100 K	(E24,E96)				
				ERA6ARC	±0.25							
				ERA6ARB	±0.1	±10	1 k to 100 k	(E24,E96)				
				ERA6ARW	±0.05							
				ERA8AHD	±0.5	±50	10 to 46.4	(E24,E96)				
				ERA8AED	±0.5	~-						
				ERA8AEC	±0.25	±25	47 to 1 M	(E24,E96)				
ERA8A	0.05	450		ERA8AEB	±0.1							
(1206)	0.25	150	300	ERA8APC	±0.25	±15	470 to 100 k	(E24,E96)				
				ERA8APB	±0.1			· · · · /				
				ERA8ARC ERA8ARB	±0.25 ±0.1	±10	1 k to 100 k					
					±0.1 ±0.05	±10		(E24,E96)				
				ERA8ARW	±0.05				<u> </u>			

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

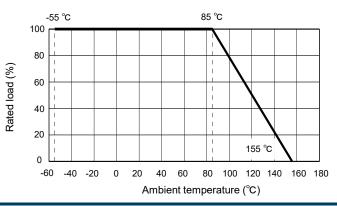
*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5) × RCWV or Maximum Overload Voltage listed above, whichever less.

*4: E192 series resistance values are also available. Please contact us for details.

*5: Duplicated resistance values between E96, E192 and E24 series shall follow E24 Part Numbers. (apply three digit resistance value)

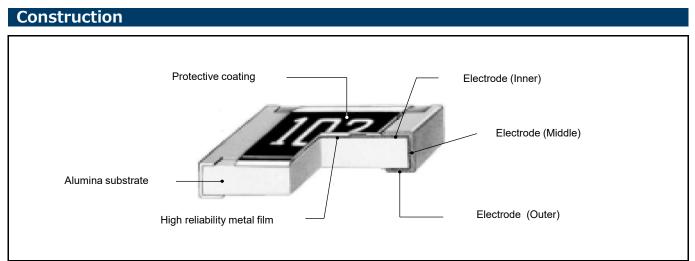
Power derating curve

For resistors operated in ambient temperatures above 85 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



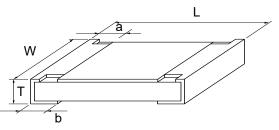
Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

Metal Film (Thin Film) Chip Resistors, High Reliability Type



*0201/0402 size or E96 series do not have value markings.

Dimensions (not to scale)



						Unit : mm	
Part No.	Dimensions						
Fait NO.	L	W	а	b	Т	 (Reference) (g/1000 pcs) 	
ERA1A	0.60±0.03	0.30±0.03	0.15±0.05	0.15±0.05	0.23±0.03	0.14	
ERA2A	1.00±0.10	0.50+0.10/-0.05	0.15±0.10	0.25±0.10	0.35±0.05	0.6	
ERA3A	1.60±0.20	0.80±0.20	0.30±0.20	0.30±0.20	0.45±0.10	2	
ERA6A	2.00±0.20	1.25±0.10	0.40±0.25	0.40±0.25	0.50±0.10	4	
ERA8A	3.20±0.20	1.60+0.05/-0.15	0.50±0.25	0.50±0.25	0.60±0.10	8	

Performance

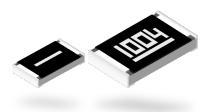
Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	R<47 Ω : ±0.5 % R≧47Ω : ±0.1 %	Rated voltage x 2.5, 5 s
Resistance to soldering heat	R<47 Ω : ±0.5 % R≧47Ω : ±0.1 %	270 ℃, 10 s
Rapid change of temperature	R<47 Ω : ±0.5 % R≧47Ω : ±0.1 %	ERA1A, 2A:–55 ℃ (30 min.) / +125 ℃ (30 min.),1000 cycles ERA3A, 6A, 8A:–55 ℃ (30 min.) / +155 ℃ (30 min.),1000 cycles
High temperature exposure	R<47 Ω : ±0.5 % R≧47Ω : ±0.1 %	+155 °C, 1000 h
Damp heat, Steady state	R<47 Ω : ±0.5 % R≧47Ω : ±0.1 %	85 ℃, 85 %RH, 1000 h
Load life in humidity	R<47 Ω : ±0.5 % R≧47Ω : ±0.1 %	85 ℃, 85%RH, 10% rated power, 1.5 h ON / 0.5 h OFF cycle, 1000 h, Max. test voltage : ERA2A : 15.8 V, ERA3A : 23.7 V, ERA6A : 31.6 V, ERA8A : 47.4 V
Endurance at 85℃	R<47 Ω : ±0.5 % R≧47Ω : ±0.1 %	85℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

High Precision Thick Film Chip Resistors

ERJ PB type

anasor



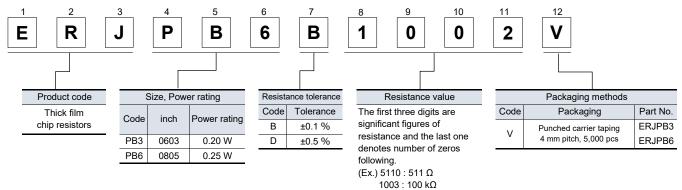
ERJ PB3, PB6 series

Features

- Achieve the resistance tolerance ±0.1 % with high reliability metal glaze thick film resistor
- Guarantee the temperature coefficient of Resistance ±50×10⁻⁶/K in high resistance range up to 1 MΩ
- High power : 0.20 W : 0603 inch /1608 mm size(ERJPB3)
 - : 0.25 W : 0805 inch /2012 mm size(ERJPB6)
- Reference Standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Ratings

Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJPB3 (0603)	0.20	150	200	±0.1 ±0.5	200 to 100 k (E24, E96)	±50	-55 to +155	Grade 0
ERJPB6 (0805)	0.25	150	200	±0.1 ±0.5	200 to 1 M (E24, E96)	±50	-33 10 + 133	Glade

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or Limiting Element Voltage listed above, whichever less.

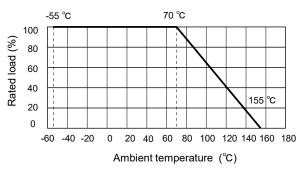
*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum overload voltage listed above, whichever less.

Power derating curve

For resistors operated in ambient temperatures

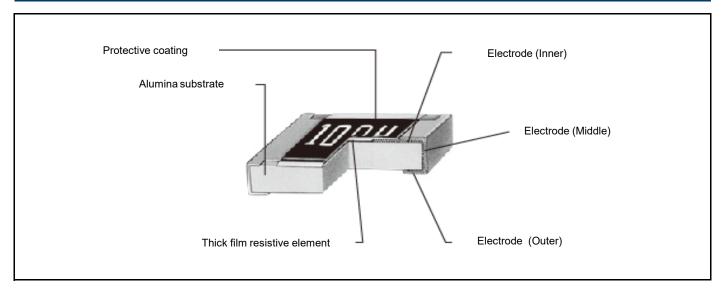
Should a safety concern arise regarding this product, please be sure to contact us immediately.

above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.

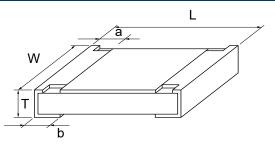


High Precision Thick Film Chip Resistors

Construction



Dimensions (not to scale)



Unit : mm

Part No.	Dimensions							
	L	W	а	b	Т	(Reference) (g/1000 pcs)		
ERJPB3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2		
ERJPB6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4		

Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±0.5 %	Rated voltage× 2.0, 5 s
Resistance to soldering heat	±0.5 %	270 °C, 10 s
Rapid change of temperature	±0.5 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±0.5 %	+155 ℃, 1000 h
Damp heat, Steady state	±0.5 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±0.5 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±0.5 %	70 $^\circ$ C, Rated voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change without house, just leave, just Should a safety concern arise regarding this product, please be sure to contact us immediately. 21

Panasonic

INDUSTRY

Thick Film Chip Resistors

(Low Resistance Type)

ERJ type

ERJ 2LW, 3LW, 6LW series

BIO EDV

ERJ 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series

ERJ 2BS/Q, 3BS/Q, 6DS/Q, 6BS/Q, 8BS/Q, 14BS/Q series ERJ 3RS/Q, 6RS/Q, 8RS/Q, 14RS/Q, 12RS/Q, 12ZS/Q, 1TRS/Q series ERJ L03, L06, L08, L14, L12, L1D series

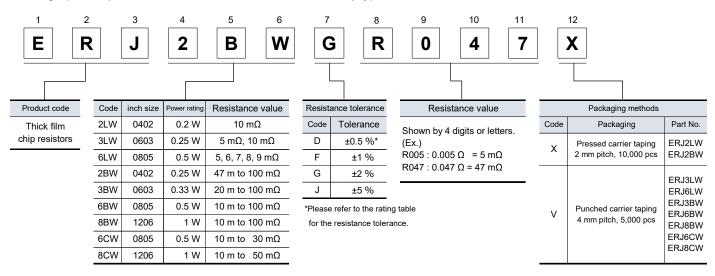
Features

- Current sensing resistor
- Small size and lightweight
- Realize both low-resistance & High-precision by original thick film resistive element & special electrode structure
- Suitable for both reflow and flow soldering
- Realize High-power by double-sided resistive elements structure that aimed to suppress temperature rising
 - : ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW
- Low TCR
- : ±75×10⁻⁶/K(ERJ6CW, ERJ8CW)
- Low resistance value \Box : Thick film resistors available from 5 m Ω (ERJ3LW, 6LW)
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2144
- AEC-Q200 compliant (Please contact us for automotive of ERJ*CW/LW)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

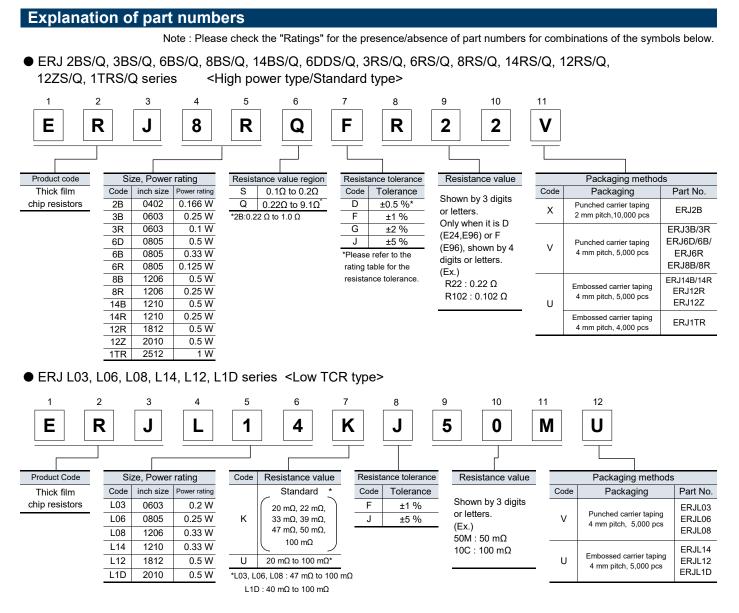
Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

ERJ 2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series
 < High power (double-sided resistive elements structure) type>



Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.



Ratings

<High power (double-sided resistive elements structure) type>

Part No. (inch size)	Power rating (70 ℃) ^{*1} (W)	Resistance tolerance (%)	Resistance range ^{*2} (Ω)	e	T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade	
ERJ2LW (0402)	0.2	±1, ±2, ±5	10 m		0 to +500			
ERJ3LW (0603)	0.25	±1, ±2, ±5	5 m		0 to +700	–55 to +125	Grade 1	
	0.25	±1, ±2, ±5	10 m		0 to +300	-33 10 1 123	Glade I	
ERJ6LW (0805)	0.5	±1, ±2, ±5	5, 6, 7, 8, 9	m	0 to +300			
ERJ2BW (0402)	0.25	±1, ±2, ±5	47 m to 100 m	(E24)	0 to +300			
ERJ3BW (0603)	0.33	±1, ±2, ±5	20 m to 100 m	(E24)	$20 \text{ m}\Omega \le \text{R} < 39 \text{ m}\Omega :_{0 \text{ to } +250}$ $39 \text{ m}\Omega \le \text{R} \le 100 \text{ m}\Omega :_{0 \text{ to } +150}$			
ERJ6BW (0805)	0.5	±1, ±2, ±5	10 m to 100 m	(E24)	10 m $\Omega \le R <$ 15 m Ω :0 to +300	–55 to +155	Grade 0	
					$15 \text{ m}\Omega \le \text{R} \le 100 \text{ m}\Omega^{:0 \text{ to } +200}$ $10 \text{ m}\Omega \le \text{R} \le 20 \text{ m}\Omega_{:0 \text{ to } +200}$			
ERJ8BW (1206)	1	±1, ±2, ±5	10 m to 100 m	(E24)	20 m $\Omega \leq$ R < 47 m Ω :0 to +150			
					47 m $\Omega \leq R \leq$ 100 m Ω ^{:0 to +100}			
ERJ6CW (0805)	0.5	±0.5, ±1, ±2, ±5	10 m to 30 m	(E24)	±75	–55 to +125	Grade 1	
ERJ8CW (1206)	1	±1, ±2, ±5	10 m to 50 m	(E24)	±75	00 10 1 120		

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Please contact us when resistors of irregular series are needed.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\/Power Rating × Resistance Value.

Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

Ratings

<High power type>

Part No. (inch size)	Power rating (70 ℃) ^{*1} (W)	Resistance tolerance (%)	Resistance range ^{*3} (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJ2BS (0402)	0.166	+1 +2 +5	0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega \ : 0 \text{ to } +300$		
ERJ2BQ (0402)	0.100	±1, ±2, ±5	0.22 to 1.0	(E24)	$0.22~\Omega \leq R \leq 1.0~\Omega$ $$: 0 to +250 $$		
ERJ3BS (0603)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R \le 0.22 \ \Omega : 0 \text{ to } +300$		
ERJ3BQ (0603)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +300 $$		
ERJ3DQ (0003)			1.0 to 9.1	(E24)	$1.0~\Omega \leq R \leq 9.1~\Omega ~: \pm 200$		
ERJ6DS (0805)			0.10 to 0.20	(E24 ^{*2})	$0.10 \ \Omega \le R \le 0.22 \ \Omega : 0 \text{ to } +150$		
ERJ6DQ (0805)	0.5	±0.5, ±1, ±2, ±5	0.22 to 9.1	(E24 ^{*2})	$0.22 \ \Omega \le R \le 1.0 \ \Omega \ : 0 \text{ to } +100$		
EK10DQ (0005)			0.22 10 9.1	(E24)	$1.0~\Omega \leq R \leq 9.1~\Omega~:\pm100$		
ERJ6BS (0805)			0.10 to 0.20	(E24)	$0.10~\Omega \leq R < 0.22~\Omega$ $$: 0 to +250 $$	–55 to +155	Grade 0
ERJ6BQ (0805)	0.33	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +250		
			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega $: ±200		
ERJ8BS (1206)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +250$	-	
	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +250		
ERJ8BQ (1206)			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega $: ±200		
ERJ14BS (1210)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R \le 0.22 \ \Omega \ : 0 \text{ to } +200$		
ERJ14BQ (1210)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +200		
ERJ 14DQ (1210)			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 100$		

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: E96 series resistance values are also available. Please contact us for details.

*3: Please contact us when resistors of irregular series are needed.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\/Power Rating × Resistance Value.

• Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

<Standard type>

Part No. (inch size)	Power rating (70 ℃) ^{*1} (W)	Resistance tolerance (%)	Resistance range ^{*2} (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJ3RS (0603)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R \le 0.22 \ \Omega \ : 0 \text{ to } +300$		
ERJ3RQ (0603)	0.1	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $~:$ 0 to +300		
			1.0 to 9.1	(E24)	$1.0~\Omega \leq R \leq 9.1~\Omega~:\pm 200$		
ERJ6RS (0805)			0.10 to 0.20	(E24)	$0.10~\Omega \leq R < 0.22~\Omega$ $$: 0 to +250		
ERJ6RQ (0805)	0.125	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +250 $$		
			1.0 to 9.1	(E24)	$1.0~\Omega \leq R \leq 9.1~\Omega ~: \pm 200$		
ERJ8RS (1206)			0.10 to 0.20	(E24)	$0.10~\Omega \leq R < 0.22~\Omega$ $$: 0 to +250		
ERJ8RQ (1206)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +250 $$		
	06)	1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 200$			
ERJ14RS (1210)			0.10 to 0.20	(E24)	$0.10~\Omega \leq R < 0.22~\Omega$ $$: 0 to +200		
ERJ14RQ (1210)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \ \Omega \le R \le 1.0 \ \Omega \ : 0 \sim +200$	–55 to +155	Grade 0
			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 100$		
ERJ12RS (1812)			0.10 to 0.20	(E24)	$0.10~\Omega \leq R < 0.22~\Omega$ $$: 0 to +200 $$		
ERJ12RQ (1812)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +200 $$		
			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 100$		
ERJ12ZS (2010)			0.10 to 0.20	(E24)	$0.10~\Omega \leq R < 0.22~\Omega$ $$: 0 to +200 $$		
ERJ12ZQ (2010)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +200 $$		
			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 100$		
ERJ1TRS (2512)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R \le 0.22 \ \Omega \ : 0 \text{ to } +200$		
ERJ1TRQ (2512)	1	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +200 $$		
			1.0 to 9.1	(E24)	$1.0 \ \Omega \le R \le 9.1 \ \Omega \ : \pm 100$		

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Please contact us when resistors of irregular series are needed.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value.

Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

Ratings

<Low TCR type>

Part No. (inch size)	Power rating (70 ℃) ^{*1} (W)	Resistance tolerance (%)	Resistance range ^{*2} (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJL03 (0603)	0.2	±1, ±5	47 m to 100 m	±200		
ERJL06 (0805)	0.25	±1, ±5	47 m to 100 m	±100		
ERJL08 (1206)	0.33	±1, ±5	47 m to 100 m	±100	-55 to +125	Grade 1
ERJL14 (1210)	0.33	±1, ±5	20 m to 100 m	D (47 m 0) 1000	-33 10 1 123	Orace 1
ERJL12 (1812)	0.5	±1, ±5	20 m to 100 m	R < 47 mΩ : ±300 R ≥ 47 mΩ : ±100		
ERJL1D (2010)	0.5	±1, ±5	40 m to 100 m			

*1: Use it on the condition that the case temperature is below the upper category temperature.

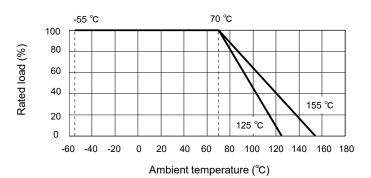
*2: Standard R.V. : 20 m Ω , 22 m Ω , 33 m Ω , 39 m Ω , 47 m Ω , 50 m Ω , 100 m Ω , Custom R.V. : Each 1 m Ω within upper range.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= / Power Rating × Resistance Value.

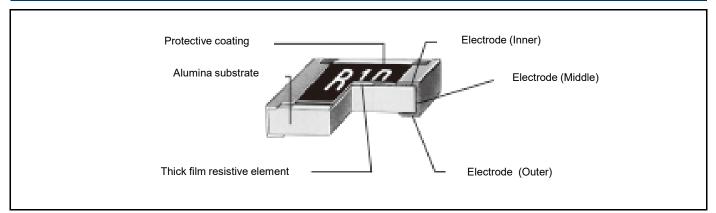
· Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Power derating curve

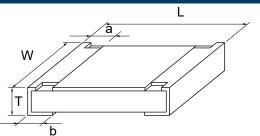
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions (not to scale)



		D				Unit : mm Mass (Weight)
Part No.		147	Dimensions		-	(Reference)
	L	W	a	b	T	(g/1000 pcs)
ERJ2LW	1.00±0.10	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.40±0.05	0.8
ERJ2BW	1.00±0.10	0.50+0.10/-0.05	0.24±0.10	0.24±0.10	0.35±0.05	0.8
ERJ2B	1.00±0.10	0.50+0.10/-0.05	0.20±0.10	0.27±0.10	0.35±0.05	0.8
ERJ3LW (5 mΩ)	1.60±0.15	0.80±0.15	0.50±0.20	0.50±0.20	0.55±0.10	3
ERJ3LW (10 mΩ) ERJ3BW	1.60±0.15	0.80±0.15	0.40±0.20	0.40±0.20	0.55±0.10	3
ERJ3R ERJ3B ERJL03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2
ERJ6LW	2.00±0.20	1.25±0.20	0.63±0.20	0.63±0.20	0.70±0.10	6
ERJ6BW	2.00±0.20	1.25±0.20	0.55±0.20	0.55±0.20	0.65±0.10	6
ERJ6CW (10 to 13 mΩ)	0.05+0.00	4 20 10 20	0.60±0.20	0.60±0.20	0.05+0.40	
ERJ6CW (15 to 30 mΩ)	- 2.05±0.20 1.30±0.20		0.45±0.20	0.45±0.20	- 0.65±0.10	6
ERJ6D	2.00±0.20	1.25±0.10	0.40±0.20	0.55±0.25	0.60±0.10	5
ERJ6R ERJ6B ERJL06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	5
ERJ8BW	3.20±0.20	1.60±0.20	1.00±0.20	1.00±0.20	0.65±0.10	13
ERJ8CW (10 to 16 mΩ)	3.20±0.20	1.60±0.20	1.10±0.20	1.10±0.20	0.65±0.10	13
ERJ8CW (18 to 50 mΩ)	3.20±0.20	1.60±0.20	0.60±0.20	0.60±0.20	0.65±0.10	13
ERJ8R ERJ8B ERJL08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10
ERJ14R ERJ14B ERJL14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16
ERJ12R ERJL12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27
ERJ12Z ERJL1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27
ERJ1TR	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45

Design and specifications are each subject to change without house. For some set, the set of the se Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Performance

• ERJ2 LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series <High power (double-sided resistive elements structure) type>

Test item	Performance requirements ⊿R	Test conditions			
Resistance	Within specified tolerance	20 °C			
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C			
Overload	±2 %	ERJ6LW : Rated voltag× 1.77, 5 s ERJ8BW (R > 0.05 Ω) : Rated voltag× 1.77, 5 s Other : Rated voltag× 2.0, 5 s			
Resistance to soldering heat	±1 %	270 °C, 10 s			
Rapid change of temperature	±1 % ERJ2LW : ±2 %	–55 ℃ (30min.) / +155 ℃ (ERJ⊡LW, ERJ⊡CW : +125 ℃) (30 min.), 100 cycles			
High temperature exposure	±1 %	+155 ℃ (ERJ□LW, ERJ□CW : +125 ℃), 1000 h			
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h			
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			

• ERJ 2BS/Q, 3BS/Q, 6BS/Q, 8BS/Q, 14BS/Q, 6DDS/Q, 3RS/Q, 6RS/Q, 8RS/Q, 14RS/Q, 12RS/Q, 12ZS/Q, 1TRS/Q series <High power type/Standard type>

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±2 %	Rated voltage× 2.5 (ERJ6D : ×1.77), 5 s
Resistance to soldering heat	±1 %	270 °C, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

ullet ERJ L03, L06, L08, L14, L12, L1D series < Low TCR type >

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±2 %	Rated voltage× 2.5, 5 s
Resistance to soldering heat	±1 %	270 °C, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +125 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+125 ℃, 1000 h
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change without notice, rock tasks, i.e. Should a safety concern arise regarding this product, please be sure to contact us immediately. 27





This series is not a recommended product. Not recommended for new design.

Current Sensing Resistors, Metal Plate Type

ERJ MS, MB type

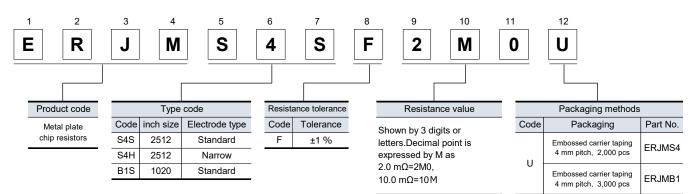
ERJ MS4, MB1 series

Features

- Ideal for current sensing solution
- Small case size with high power
- Metal plate bonding technology. Excellent long term stability
- Outer Resin with high heat dissipation. Wide temperature range (-65 °C to +170 °C)
- AEC-Q200 compliant
- RoHS compliant
- ISO9001, ISO/TS16949 certified
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Ratings

Part No. (inch size)	Power rating (70 ℃) (W)	Resistance range (mΩ)	Resistance tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	Terminal temp. upper limit (℃)	AEC-Q200 Grade
ERJMS4S (2512)	3	1, 2, 3, 4	F : ±1	±75		130	
ERJMS4H	3	5, 6	F : ±1	±75	_65 to +170		Grade 0
(2512)	2	7, 8, 9, 10	F : ±1	±75	-05 10 +170	100	Grade 0
ERJMB1S (1020)	2	1, 2, 3, 4, 5	F : ±1	±75		130	

* Please contact us when resistors of irregular series are needed.

Power derating curve

If the terminal temperature of the resistor is more

than terminal temperature upper limit value of the

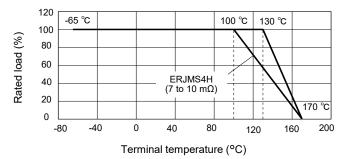
rated table, please reduce the rated power according

to the Power Derating Curve shown in the figure on the right. <Supplemented>

In the case of the temperature measurement of the terminal portion of the resistor, Please perform under the following conditions.

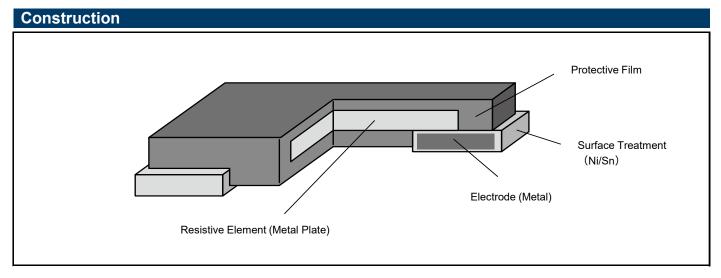
1) Terminal temperature measurement, please apply the temperature of the higher of either the left or right electrode upper surface of the resistor.

2) Please measure the temperature of the resistor in the land pattern printed of circuit board and plan to use by real conditions

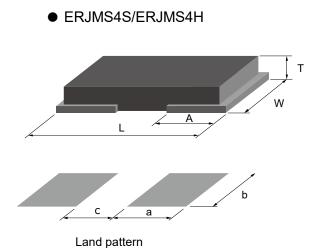


Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

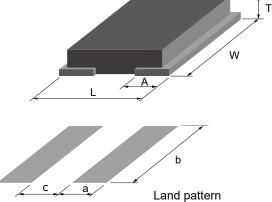
Current Sensing Resistors, Metal Plate Type



Dimensions in mm (not to scale), Recommended land pattern



• ERJMB1S

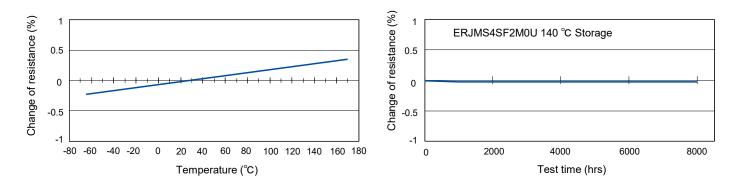


Unit : mm

Part No.		Dime	Recom	Mass (Weight) (Reference)				
	L	W	A	Т	а	b	с	(g/1000 pcs)
ERJMS4S	6.40±0.25	3.20±0.25	2.20±0.25	1.20±0.15	2.7	3.4	2.0	120
ERJMS4H	6.40±0.25	3.20±0.25	1.25±0.25	1.20±0.15	1.7	3.4	4.0	115
ERJMB1S	2.55±0.25	5.00±0.25	0.68 +0.15/-0.20	0.90±0.15	1.15	5.5	1.1	40



Long-term stability



29

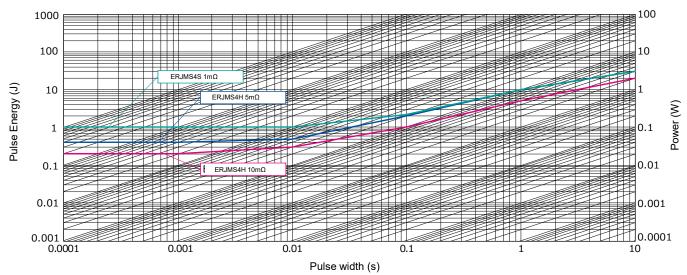
Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Maximum pulse energy respectively pulse power for continuous operation

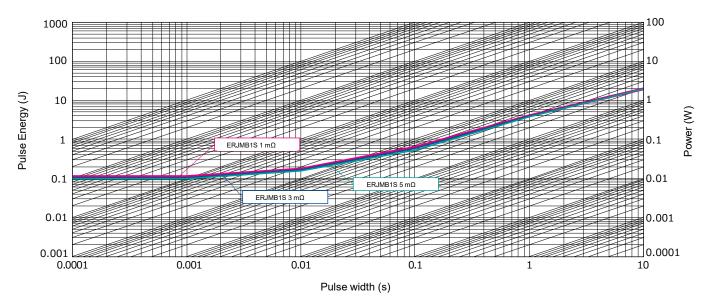
Referance Data

Condition : Room Temperature, OFF : 10 s, 1000 cycle, Wave form : Square Change of Resistance = ± 1 %

ERJMS4S/ERJMS4H



• ERJMB1S



Current Sensing Resistors, Metal Plate Type

Performance (AEC-Q200)

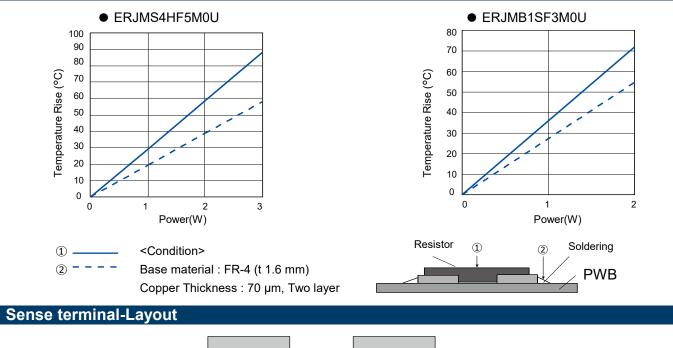
• ERJMS4S/ERJMS4H

Test item	Performance requirements ⊿R	Typical value ⊿R	Test condition
Thermal shock	±1 %	0.20 %	–55 ℃ /+155 ℃,1000 cycles
Overload	±0.5 %	0.10 %	Rated power x 3, 5 s
Solderability	> 95% coverage	> 95% coverage	245 ℃, 3 s
Resistance to solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low temperature storage and operation	±0.5 %	0.03 %	–65 ℃, 24 h
Resistance to soldering heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 ℃, 10 s)
Moisture resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 ℃, Rated Power, 2000 h
Storage life at elevated temperature	±1 %	0.30 %	170 ℃, 2000 h
High temperature characteristics	±0.5 %	0.05 %	140 ℃, 2000 h
Frequency characteristics	< 5 nH	< 2 nH	Inductance

• ERJMB1

Test item	Performance requirements ⊿R	Typical value ⊿R	Test condition
Thermal shock	±1 %	0.30 %	–55 ℃ /+155 ℃, 1000 cycles
Overload	±1 %	0.30 %	Rated power x 2.5, 5 s
Solderability	> 95% coverage	> 95% coverage	245 ℃, 3 s
Resistance to solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low temperature storage and operation	±0.5 %	0.03 %	–65 ℃, 24 h
Resistance to soldering heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 ℃, 10 s)
Moisture resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 ℃, Rated Power, 2000 h
Storage life at elevated temperature	±1 %	0.30 %	170 ℃, 2000 h
High temperature characteristics	±0.5 %	0.05 %	140 ℃, 2000 h
Frequency characteristics	< 5 nH	< 2 nH	Inductance

Temperature rise





Design and specifications are each subject to change without house, it is the subject to change without house, it is the subject to change without house. The subject to change without house, it is the subject to change without house. The subject to change without house, it is the subject to change without house. The subject to change without house, it is the subject to change without house. The subject to change without house, it is the subject to change without house. The subject to change without house, it is the subject to change without house. The subject to change without house, it is the subject to change without house. The subject to change without house, it is the subject to chouse, it is the subject to change without house, it is the sub Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

anasonic

INDUSTRY

High Power Chip Resistors (Wide Terminal Type) ERJ A, B type

ERJ A1, B1, B2, B3 series

Features

- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

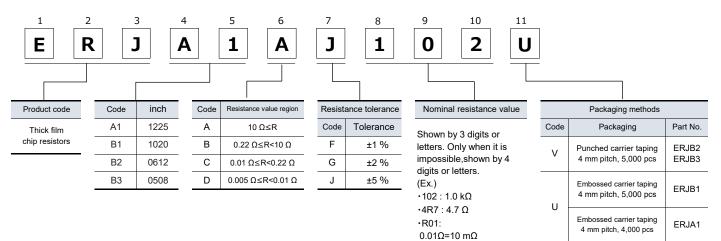
Recommended applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

•R015 0.015Ω=15 mΩ R10 R10





High Power Chip Resistors (Wide Terminal Type)

Part No. (inch size)	Power rating ^{*1} (W)	Rated ambient temperature ^{*2} (℃)	Rated terminal part temperature ^{*2} (℃)	Limiting element voltage ^{*3} (V)	Maximum overload voltage ^{*4} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade	
ERJA1	1.33	70		200	400	±1	100m to 10k (E24)	±100			
(1225)	1.55	70	-	200	400	±2, ±5	10m to 10k (E24)	10mΩ≤R<100mΩ ∶ ±350 100mΩ≤R≤10kΩ ∶ ±200			
						±1	40 4 40	±1 %: 10mΩ≤R<22mΩ:0 to +350			
ERJB1	2 (R≤10Ω)	70	125	200	400	±2, ±5	10m to 10 (E24)	22mΩ≤R<47mΩ : 0 to +200 47mΩ≤R<100mΩ : 0 to +150 100mΩ≤R≤10kΩ : ±100			
(1020)	1	70	95	200		±1	11 to 10k	±2 %, ±5 % : 10mΩ≤R<22mΩ : 0 to +350			
	(R>10Ω)	70	95			±2, ±5	(E24)	22mΩ≤R<100mΩ:0 to +200 100mΩ≤R≤10kΩ :±200			
	1.5 (R≤1kΩ)	-	125			±1 ±2, ±5	10m to 1k (E24)	±1%:			
	0.75 (R>1kΩ)	-	90				±1 ±2, ±5	1.1k to 1M (E24)	10mΩ≤R<22mΩ:0 to +300 22mΩ≤R<47mΩ:0 to +200		
						±1 ±2	10m to 10 (E24)	47mΩ≤R<100mΩ:0 to +150 100mΩ≤R≤220mΩ:0 to +100	-55 ~ +155	Grade 0	
ERJB2 (0612)	1 (R≤10Ω)	70	200	400		5, 6, 7, 8,	220mΩ≤R≤1MΩ : ±100 ±2 %, ±5 % :				
	(113 1022)		-			±5	9,10m to 10 (E24)	5mΩ≤R<22mΩ : 0 to +300 22mΩ≤R<47mΩ : 0 to +200 47mΩ≤R<100mΩ : 0 to +150			
	0.75	70				±1	11 to 1M	100mΩ≤R<220mΩ:0 to +200 220mΩ≤R≤1MΩ:±200			
	(R>10Ω)	70				±2, ±5	(E24)				
	1	-	105			±1 ±2, ±5	20m to 10 (E24)	±1%: 20mΩ≤R<47mΩ:0 to +300 47mΩ≤R<1Ω:0 to +200			
ERJB3	0.5			150	200	150 200	±1	20m to 1	1Ω≤R≤10Ω ∶±100		
(0508)	(R≤1Ω)	70	-			±2, ±5	(E24)	± 2 %, ± 5 % : 20mΩ≤R<47mΩ : 0 to +300			
	0.33 (R>1Ω)	70	-			±1 ±2, ±5	1.1 to 10 (E24)	47mΩ≤R<1Ω ∶ 0 to +200 1Ω≤R≤10Ω ∶ ±200			

*1: Use it on the condition that the case temperature is below the upper category temperature.

Ratings

*2: If there is a doubt whether the rated ambient temperature or the rated terminal part temperature is used, give priority to the rated terminal part temperature.

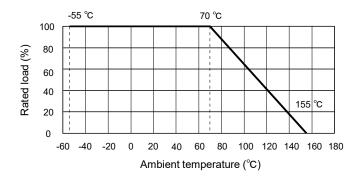
- *3: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- *4: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Ratings

Power derating curve

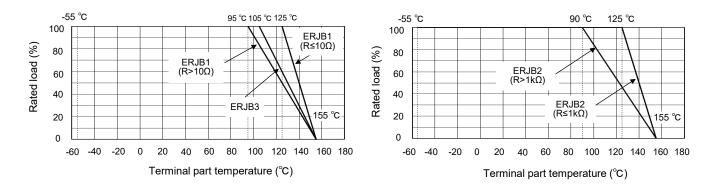
• For resistors operated in ambient rated ambient temperature, power rating shall be derated in accordance with the figure below.

In addition, please use under the condition that the product temperature is below the upper category temperature.

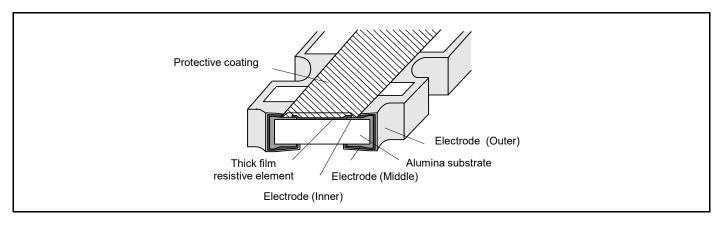


•For resistors operated in ambient rated terminal part temperature, power rating shall be derated in accordance with the figure below.

In addition, please use under the condition that the product temperature is below the upper category temperature.

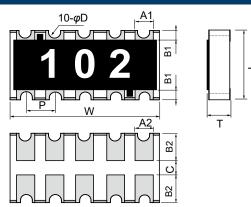


Construction (Example : ERJA1 type)

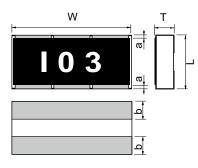


High Power Chip Resistors (Wide Terminal Type)

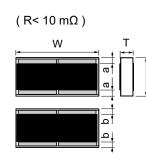
Dimensions (not to scale)



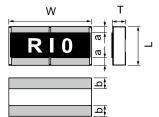
Part No.	Dimensions								
Fait NO.	L	W	A ₁	B ₁	Т	(Reference) (g/1000 pcs)			
	3.20±0.20	6.40±0.20	0.70±0.20	0.45±0.20	0.55±0.10				
ERJA1	A ₂	B ₂	Р	øD	С	40			
	0.70±0.20	1.25±0.15	1.27±0.10	0.30+0.10/-0.20	0.4 min.				



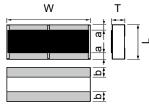
Part No.	Dimensions							
Part No.	L	W	а	b	Т	 (Reference) (g/1000 pcs) 		
ERJB1	2.50±0.20	5.00±0.20	0.25±0.20	0.90±0.20	0.55±0.20	27		







Unit : mm Part No. Dimensions Mass (Weight) (Reference) (g/1000 pcs) ERJB2 W Т L а b 0.30±0.20 0.65±0.15 5 mΩ≤R<10 mΩ 0.30±0.20 10 mΩ≤R<220 mΩ 1.60±0.15 3.20±0.20 11 0.50±0.20 0.55±0.15 220 mΩ≤R≤1 MΩ 0.25±0.20



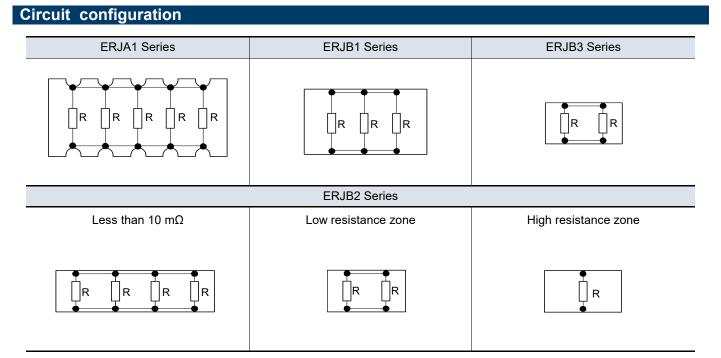
						Unit : mm		
Dort No.	Dimensions							
Part No.	L	W	а	b	Т	(Reference) (g/1000 pcs)		
ERJB3	1.25±0.10	2.00±0.15	0.25±0.20	0.40±0.20	0.50±0.10	4.8		

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Should a safety concern arise regarding this product, please be sure to contact us immediately.

Unit : mm

High Power Chip Resistors (Wide Terminal Type)



Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±2 %	ERJA1, ERJB1 (1W) : Rated voltag x 2.5, 5 s ERJB2 (0.75 W) : Rated voltag x 2.2, 5 s ERJB1 (2 W), ERJB2 (1.5 W, 1 W), ERJB3 : Rated voltag x 2.0, 5 s
Resistance to soldering heat	±1 %	270℃, 10 s
Rapid change of temperature	±2 %	–55 ℃ (30 min.) / +125 ℃ (30 min.), 1000 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity 1 (Applicable to rated ambient temperature-regulated products)	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage 1.5 h ON / 0.5 h OFF cycle, 1000 h
Load life in humidity 2 (Applicable to rated ambient temperature-regulated products)	±3 %	85 °C, 85 %RH, Rated power 10%, Continuously power, 1000 h
Durability at rated ambient temperature or rated terminal part temperature	±3 %	Rated ambient temperature or rated terminal part temperature, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

36

Panasonic

INDUSTRY

Low TCR High Power Chip Resistors (Wide Terminal Type)



ERJ D type

ERJ D1, D2 series

Features

- Achieved High power and low TCR (±100×10⁻⁶/K) using wide terminal electrode structure and original material
- Suitable for small size/high power current detection (Low TCR enables high accuracy of current detection)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below. 1 2 6 8 9 10 11 12 Ε R J 1 F R 0 1 0 U D D Product code Resistance value Packaging methods Power Resistance Code inch Resistance value region rating tolerance Code Part No. Packaging Thick film Shown by 4 digits or chip resistors D1C $22 \text{ m}\Omega \leq R \leq 200 \text{ m}\Omega$ Code Tolerance letters Embossed carrier taping FR.ID1 1020 2 W υ 4 mm pitch, 5,000 pcs D1D $10 \text{ m}\Omega \leq R \leq 20 \text{ m}\Omega$ ±1 % (Ex.) F •R010: D2C 33 mΩ ≤R≤ 200 mΩ J ±5 % Punched carrier taping 0612 1 W v ERJD2 0.010 Ω=10 mΩ D2D 4 mm pitch, 5,000 pcs $10 \text{ m}\Omega \leq R \leq 30 \text{ m}\Omega$

Ratings

Part No. (inch size)	Power rating (70 ℃) ^{*1} (W)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade
ERJD1 (1020)	2	±1, ±5	10 m to 200 m (E24)	±100	–55 to +155	Grade 0
ERJD2 (0612)	1	±1, ±5	10 m to 200 m (E24)	±100	-00 10 +100	Grade U

*1: Use it on the condition that the case temperature is below the upper category temperature.

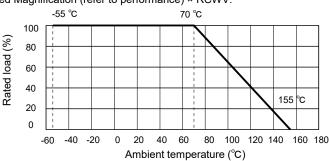
· Please contact us when resistors of irregular series are needed.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\/Power Rating × Resistance Value.

Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV.

Power derating curve

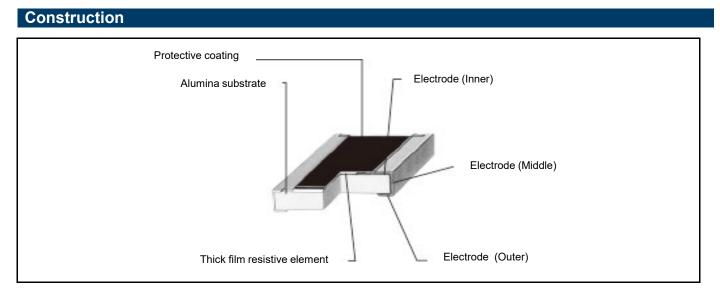
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



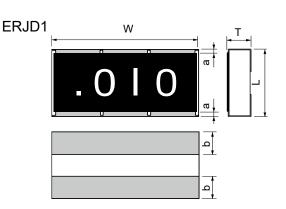
Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

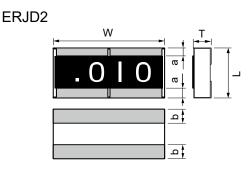
37

Low TCR High Power Chip Resistors (Wide Terminal Type)



Dimensions (not to scale)

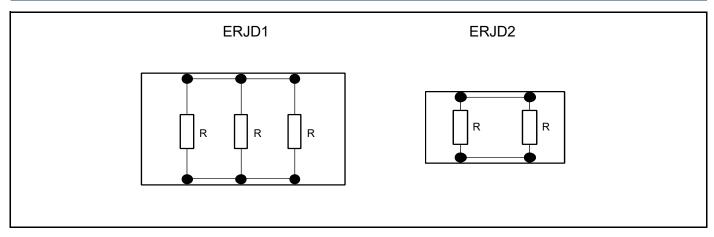




Unit : mm

Part No.	Dimensions							
Fall NO.	L	W	а	b	Т	 (Reference) (g/1000 pcs) 		
ERJD1	2.50±0.20	5.00±0.20	0.30±0.20	0.90±0.20	0.60±0.20	27		
ERJD2	1.60±0.15	3.20±0.20	0.30±0.20	0.50±0.20	0.65±0.15	11		

Circuit configuration



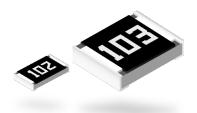
Low TCR High Power Chip Resistors (Wide Terminal Type)

Performance		
Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±2 %	Rated voltag x 2.0, 5 s
Resistance to soldering heat	±1 %	270 °C, 10 s
Rapid change of temperature	±2 %	–55 ℃ (30 min.) / +125 ℃ (30 min.), 1000 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 $^\circ C$, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Panasonic

INDUSTRY

Anti-Surge Thick Film Chip Resistors ERJ P, PA,PM type ERJ PA2, PA3, P03, P06, P08, PM8, P14 series



Features

- ESD surge characteristics superior to standard metal film resistors
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power 0.20 W : 0603 inch / 1608 mm size (ERJP03)
 - 0.20 W : 0402 inch / 1005 mm size (ERJPA2)
 - 0.33 W : 0603 inch / 1608 mm size (ERJPA3)
 - 0.50 W : 0805 inch / 2012 mm size (ERJP06), 1210 inch / 3225 mm size (ERJP14)
 - 0.66 W : 1206 inch / 3216 mm size (ERJP08)
- High precision, High voltage, High resistance value (ERJPM8)

: Limiting element voltage 500 V, Resistance tolerance ±1 %, TCR ±100 (x 10⁻⁶ / K)

- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below. 10 11 12 Ε R J Ρ 1 0 2 0 6 D 0 V Nominal resistance value Product code Code inch size Resistance tolerance Packaging methods PA2 0402 Code Tolerance Code Packaging Part No. Thick film Three digit type (±5 %), chip resistors PA3 D ±0.5 % Four digit type (±1 %, ±0.5 %) Punched carrier Ttaping 0603 Х ERJPA2 Example: 2 mm pitch, 10,000 pcs F P03 +1 % 222 : 2.2 KΩ P06 0805 10R0 : 10 Ω J +5 % ERJPA3 1002 : 10 KΩ ERJP03 P08 Punched carrier taping 1206 V FR.IP06 4 mm pitch, 5,000 pcs PM8 ERJP08 ERJPM8 P14 1210 Embossed carrier taping U ERJP14 4 mm pitch, 5,000 pcs

Anti-Surge Thick Film Chip Resistors

Ratings																					
Part No. (inch size)	Power rating ^{*1} (W)	Rated ambient temperature ^{*2} (℃)	Rated terminal part temperature ^{*2} (℃)	Limiting element voltage ^{*3} (V)	Maximum overload voltage ^{*4} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade											
						±0.5, ±1	10 to 1M (E24, E96)														
ERJPA2	0.20	70	-	50	100	±5	Resistance value expansion 1 to 1M (E24)	±0.5, ±1 : ±100 ±5 : ±200	Grav	Grade 1											
(0402)						±0.5, ±1	10 to 1M (E24, E96)	R<10Ω : -100 to +600													
0.2	0.25	-	100			±5	Resistance value expansion 1 to 1M (E24)														
	0.25	105		±0.5, ±1 10 to 1M (E24, E96)																	
ERJPA3 (0603)	0.25	0.25 105	-	150		±5	1 to 1.5M (E24)	±0.5, ±1 : ±100													
	0.22	0.33 -												130	150	200	±0.5, ±1	10 to 1M (E24, E96)	±5 : ±200		
	0.33					±5	1 to 1.5M (E24)														
		0.20 70															±0.5	10 to 1M (E24, E96)	±150	–55 to +155	
ERJP03 (0603)	0.20		-	- 150	200	±1	10 to 1M (E24, E96)	R<10Ω : –150 to +400 10Ω≤R : ±200													
						±5	1 to 1M (E24)														
						±0.5, ±1	10 to 1M (E24, E96)	R<33Ω :±300 33Ω≤R :±100		Grade 0											
ERJP06 (0805)	0.50	70	115	115 400	600	±5	1 to 3.3M (E24)	R<10Ω [∶] −100 to +600 10Ω≤R<33Ω [∶] ±300 33Ω≤R [∶] ±200													
ERJP08	0.00	70	405	500	1000	±0.5, ±1	10 to 1M (E24, E96)	±100													
(1206)	0.66	70	125	500	1000	±5	1 to 10M (E24)	R<10Ω ∶ –100 to +600 10Ω≤R ∶ ±200													
ERJPM8 (1206)	0.66	70	125	500	1000	±1	1.02M to 10M (E24, E96)	±100													
ERJP14	0.50				400	±0.5, ±1	10 to 1M (E24, E96)	±100	1												
(1210)	0.50	70	-	- 200		±5	1 to 1M (E24)	R<10Ω ∶ −100 to +600 10Ω≤R ∶ ±200													

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: If there is a doubt whether the rated ambient temperature or the rated terminal part temperature is used, give priority to the rated terminal part temperature.

*3: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

*4: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

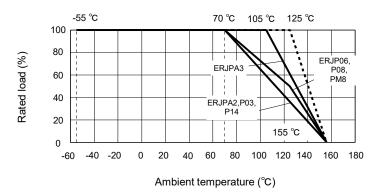
Ratings

Power derating curve

•For resistors operated in ambient rated ambient temperature, power rating shall be derated in accordance with the figure below.

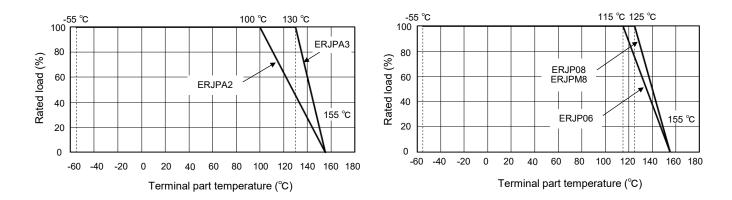
In addition, please use under the condition that the product temperature is below the upper category temperature.

% When the temperature of ERJP14 is 155 $^{\circ}$ C or less, the derating start temperature can be changed to 125 $^{\circ}$ C. (See the dotted line)

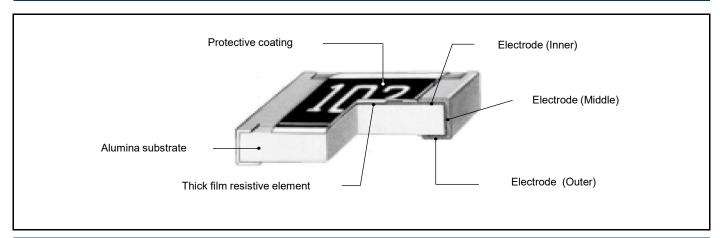


•For resistors operated in ambient rated terminal part temperature, power rating shall be derated in accordance with the figure below.

In addition, please use under the condition that the product temperature is below the upper category temperature.

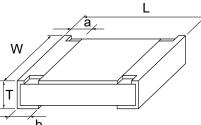


Construction



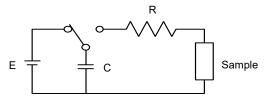
Anti-Surge Thick Film Chip Resistors

Dimensions (not to scale)

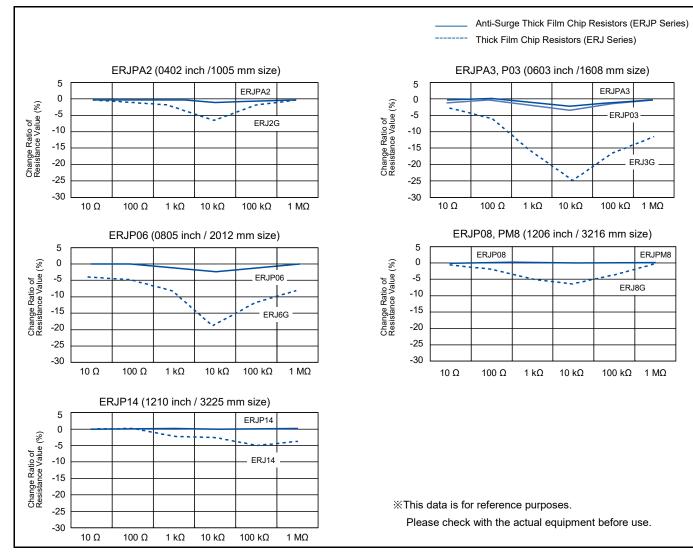


D								
Part No.			Dimensions			Mass (Weight) (Reference)		
	L	W	а	b	Т	(g/1000 pcs)		
ERJPA2	1.00±0.05	0.50±0.05	0.20±0.15	0.25±0.10	0.35±0.05	0.8		
ERJPA3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2		
ERJP03	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.30±0.15	0.45±0.10	2		
ERJP06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4		
ERJP08,PM8	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10		
ERJP14	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16		

ESD Characteristic



Size (inch)	0402	0603, 0805, 1206, 1210
R	1.5 kΩ	R=0 Ω (≤1.5 kΩ) / 150 Ω > 1.5 kΩ)
С	100 pF	150 pF
E	±1 kV	±3 kV



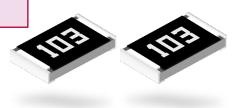
Anti-Surge Thick Film Chip Resistors

Performance

-		—
Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃ (ERJPA2 : +125 ℃)
	±2 %	ERJP06:Rated voltag× 1.77, 5 s
Overload	Only when it is ERJP03 (D),	ERJPA2, ERJPA3, ERJP08, ERJPM8 : Rated voltag× 2.0, 5 s
	P14 (D) : ±0.5 %	ERJP03, ERJP14 : Rated voltag× 2.5, 5 s
Resistance to soldering heat	D:±0.5 %, F, J:±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30min.) / +155 ℃ (ERJPA2 : +125 ℃) (30min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity 1 (Applicable to rated ambient temperature-regulated products)	±3 % Only when it is ERJP03 (D), P14 (D) : ±1 %	60 ℃, 90 % to 95 %RH, Rated voltage <i>,</i> 1.5 h ON / 0.5 h OFF cycle, 1000 h
Load life in humidity 2 (Applicable to rated terminal part temperature-regulated products)	±3 %	85 °C, 85 %RH, Rated power 10%, Continuously power, 1000 h
Durability at rated ambient temperature or rated terminal part temperature	±3 % Only when it is ERJP03 (D), P14 (D) : ±1 %	Rated ambient temperature or rated terminal part temperature, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h







(Double-sided resistive elements structure) ERJ P W type

ERJ P6W series

Features

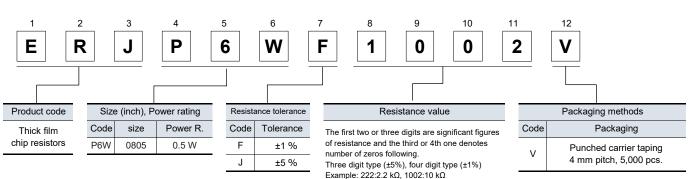
• ESD surge characteristics superior to standard metal film resistors

Anti-Surge Thick Film Chip Resistors

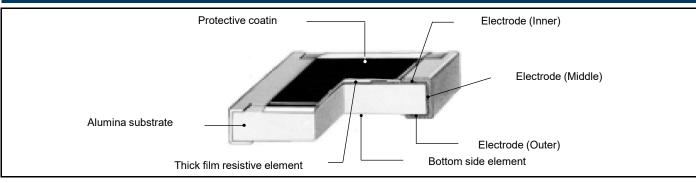
- Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power
- High pulse characteristics
- : 0.50 W, 2012(0805) size(ERJP6W)
- : 1.5 times higher than 0805 inch size Anti-Surge thick film chip resistors (ERJP06)
- Reference standards
- : IEC 60115-8、 JIS C 5201-8、 EIAJ RC-2134B
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

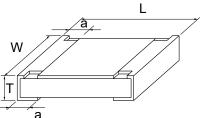
Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Construction



Dimensions in mm (not to scale)



a								
Type		Mass (Weight)						
Туре	L	W	а	Т	(g/1000 pcs)			
ERJP6W (0805)	2.00±0.20	1.25±0.20	0.35±0.20	0.65±0.10	6			

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change management of the sector of the s

Anti-Surge Thick Film Chip Resistors (Double-sided resistive elements structure)

Ratings	Ratings										
Part No. (inch size)	Power rating ^{*1} (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3}	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (°C)				
ERJP6W	ERJP6W 0.5	150 200	200	± 1	10 to 1 M (E24,E96)	± 200	-55 to +155				
(0805)	0.5		200	± 5	1 to 1 M	R < 10 Ω : -100 to +600					
					(E24)	$10 \ \Omega \leq R : \pm 200$					

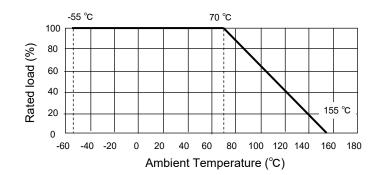
*1: Use it on the condition that the case temperature is below 155 $^\circ\!\! C.$

*2: Overload (Short-time Overload) test voltage (SOTV) shall be determined from SOTV=2.5 × Power rating or max. Over load voltage listed above whichever less.

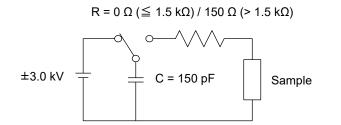
*3: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=/Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

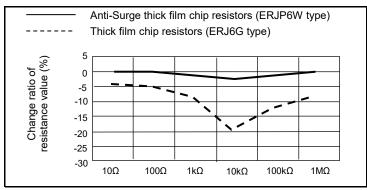
Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



ESD Characteristic

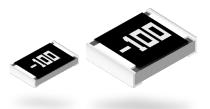




Panasonic

INDUSTRY

Anti-Pulse Thick Film Chip Resistors



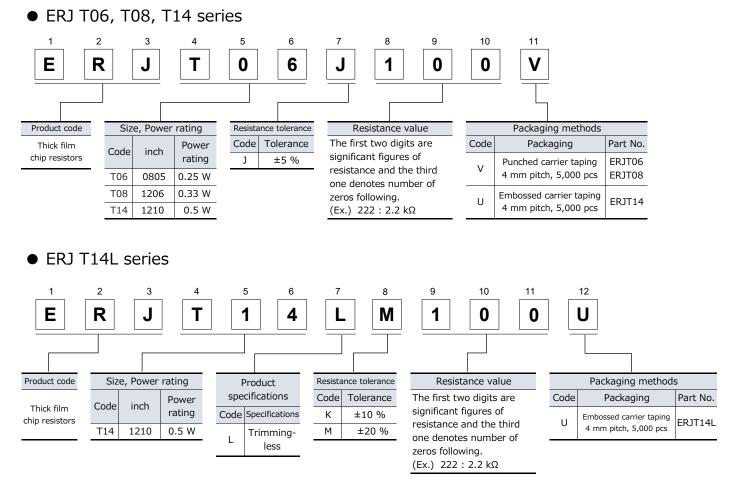
ERJ T type ERJ T06, T08, T14 series ERJ T14L series

Features

- Anti-Pulse characteristics
 High pulse characteristics achieved by the optimized trimming specifications (ERJT06, T08, T14)
- Further high pulse characteristics achieved by trimming-less specifications (ERJT14L)
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power 0.25 W : 0805 inch /2012 mm size(ERJT06)
 - 0.33 W : 1206 inch /3216 mm size(ERJT08)
 - 0.50 W : 1210 inch /3225 mm size(ERJT14, ERJT14L)
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



* Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

Anti-Pulse Thick Film Chip Resistors

Ratings

Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJT06 (0805)	0.25	150	200	±5	1 to 1 M (E24)	R<10 Ω : −100 to +600 10 Ω≤R<33 Ω : ±300		
ERJT08 (1206)	0.33	200	400	±5	1 to 1 M (E24)	33 Ω≤R : ±200 R<10 Ω : −100 to +600 10 Ω≤R : ±200	–55 to +155	Grade 0
ERJT14 (1210)	0.50	200	400	±5	1 to 1 M (E24)	R<10 Ω ∶ −100 to +600 10 Ω≤R ∶ ±200		
ERJT14L (1210)	0.50	200	400	±10 ±20	1 to 1 M (E12)	R<10 Ω ∶ −100 to +600 10 Ω≤R ∶ ±200		

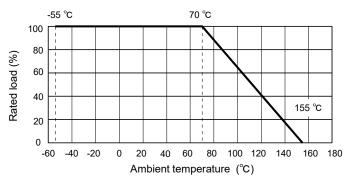
*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

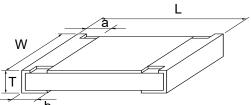
Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction Protective coating Flectrode (Inner) Electrode (Middle) Alumina substrate Thick film resistive element Electrode (Outer)

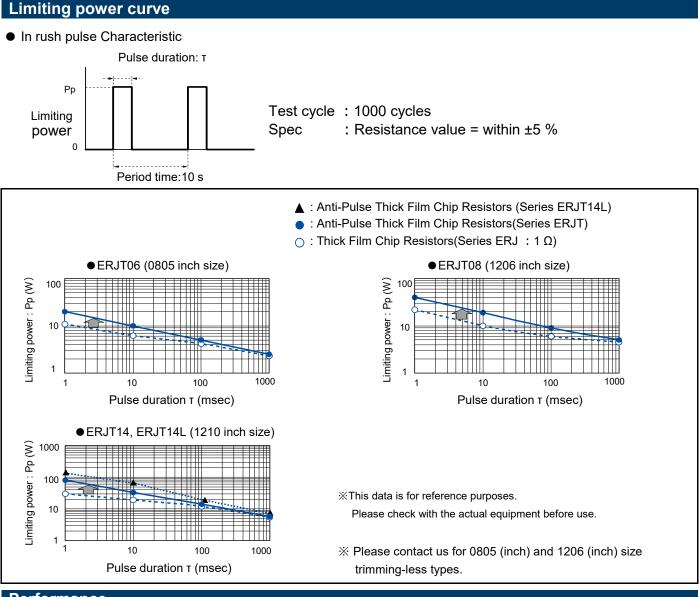
Dimensions (not to scale)



		b				Unit : mm		
Devit No	Dimensions							
Part No.	L	W	а	b	Т	(Reference) (g/1000 pcs)		
ERJT06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4		
ERJT08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10		
ERJT14 ERJT14L	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16		

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Should a safety concern arise regarding this product, please be sure to contact us immediately.



Performance

renomance				
Test Item	Performance requirements ⊿R	Test conditions		
Resistance	Within specified tolerance	20 °C		
T. C. R.	Within specified T. C. R.	+25 °C / +155 °C		
Overload	±2 %	Rated voltage× 2.5, 5 s		
Resistance to soldering heat	±1 %	270 ℃±3 ℃, 10 s ±1 s		
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles		
High temperature exposure	±1 %	+155 ℃, 1000 h		
Damp heat, Steady state	±1 %	60 ℃ ±2 ℃, 90 % to 95 %RH, 1000 h		
Load life in humidity	±3 %	60 ℃ ±2 ℃, 90 % to 95 %RH, Rated voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70℃	±3 %	70 ℃ ±2 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		

Panasonic

INDUSTRY

Anti-Sulfurated Thick Film Chip Resistors

ERJ S type (Au-based inner electrode type)

ERJ S02, S03, S06, S08, S14 series

ERJ S12, S1D, S1T series

ERJ U type (Ag-Pd-based inner electrode type)

ERJ U0X, U01, U02, U03, U06, U08, U14 series

ERJ U12, U1D, U1T, U6S, U6Q series



Features

- High resistance to sulfurization achieved by adopting an Au-based inner electrode (Series ERJS) and Ag-Pd-based inner electrode (Series ERJU)
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- Low resistance type : ERJU6S, U6Q series : 0.1 Ω to 1 Ω
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJU0X, ERJU01)
- RoHS compliant

chip resistors

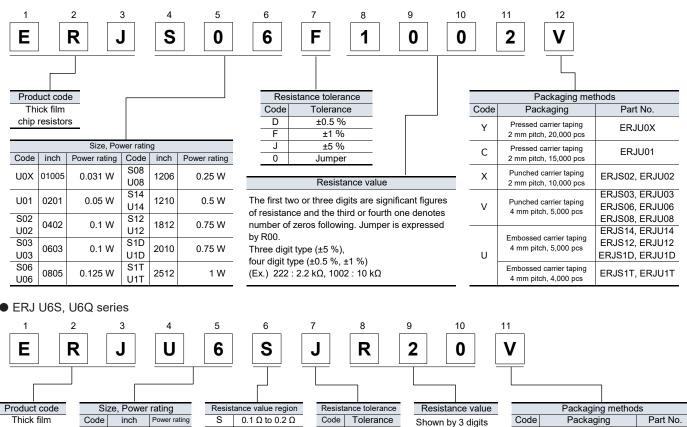
U6

0805

As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below. • ERJ S02 to ERJS1T, ERJU0X to ERJU1T series



±1%

+2 %

±5 %

or letters.

R20 : 0.20 Ω=200 mΩ 1R0 : 1.0 Ω=1000 mΩ

(Fx)

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

0.22 0 to 1.0

0 25 W

0

F

G

FRJU6S

ERJU6Q

Punched carrier taping

4 mm pitch, 5,000 pc:

V

Anti-Sulfurated Thick Film Chip Resistors

Rating	S								
Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	rai	stance nge Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade
ERJU0X (01005)	0.031	15	30	±1 ±5	10 to 1 M	(E24, E96) (E24)	R<10 Ω : −100 to +600 10 Ω≤R<100 Ω : ±300 100 Ω≤R : ±200	-55 to +125	_
ERJU01 (0201)	0.05	25	50	±1 ±5	10 to 1 M 1 to 1 M	(E24, E96) (E24)	R<10 Ω : -100 to +600		
ERJS02 ERJU02 (0402)	0.1	50	100	±0.5, ±1 ±5	1 to 1 M ERJS02: 1 to ERJU02: 1 to		10 Ω to 1 MΩ :±200 1 MΩ <r +150<="" :400="" td="" to=""><td></td><td></td></r>		
ERJS03 ERJU03 (0603)	0.1	75	150	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	-		
ERJS06 ERJU06 (0805)	0.125	150	200	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)			
ERJS08 ERJU08 (1206)	0.25	200	400	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	R<10 Ω :–100 to +600		
ERJS14 ERJU14 (1210)	0.5	200	400	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	10 Ω to 1 MΩ :±200 (± 5 %) :±100 (±0.5 %, ±1 %)	–55 to +155	Grade 0
ERJS12 ERJU12 (1812)	0.75	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td></td><td></td></r>		
ERJS1D ERJU1D (2010)	0.75	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	1		
ERJS1T ERJU1T (2512)	1.0	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	-		

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value,

or Limiting Element Voltage listed above, whichever less.

*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

[Low resistance type]

Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Resistance tolerance (%)	Resistar range (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJU6S (0805)	0.25	±1 ±2 ±5	0.1 to 0.2	(E24)	0 to +150	–55 to +155	Grade 0
ERJU6Q (0805)	0.25	±1, ±2, ±5	0.22 to 1	(E24)	0 10 + 150	-55 (0 + 155	Grade 0

*1: Use it on the condition that the case temperature is below the upper category temperature.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=/Power Rating × Resistance Value.

Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

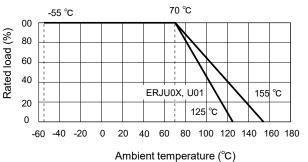
[For jumper]

Part No.	Resistance	Rated current	Maximum overload current ^{*1}
ERJU0X		0.5 A	1 A
ERJU01	- 100 mΩ or less	0.5 A	
ERJS02,ERJU02		1 A	2 A
ERJS03,ERJU03			2 A
ERJS06,ERJU06			
ERJS08,ERJU08			
ERJS14,ERJU14		2 A	4 A
ERJS12,ERJU12		27	47
ERJS1D,ERJU1D			
ERJS1T,ERJU1T			

*1: Overload test current

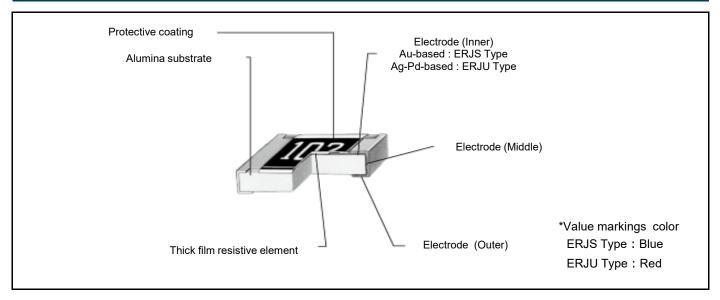
Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure below.

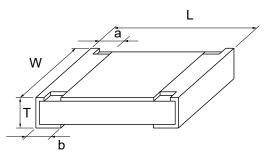


Anti-Sulfurated Thick Film Chip Resistors

Construction



Dimensions (not to scale)



Unit : mm

Part No.		Dimensions							
Part NO.	L	W	а	b	Т	 (Reference) (g/1000 pcs) 			
ERJU0X	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04			
ERJU01	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15			
ERJS02 ERJU02	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.10	0.35±0.05	0.8			
ERJS03 ERJU03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJS06 ERJU06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4			
ERJU6	2.00±0.20	1.25±0.10	0.45±0.20	0.45±0.20	0.55±0.10	6			
ERJS08 ERJU08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10			
ERJS14 ERJU14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16			
ERJS12 ERJU12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27			
ERJS1D ERJU1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27			
ERJS1T ERJU1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45			

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change without router, r

Anti-Sulfurated Thick Film Chip Resistors

Performance

• ERJ S02 to ERJS1T, ERJU0X to ERJU1T series

Test item	Performance re	equirements ⊿R	Test conditions	
restitem	Resistor type	Jumper type		
Resistance	Within specified tolerance	100 m Ω or less	20 °C	
T. C. R.	Within Specified T. C. R.	200 m Ω or less	+25 ℃ / +155 ℃ (ERJU0X,U01 : +25 ℃ / +125 ℃)	
Overload	±2 %	100 m Ω or less	Rated voltage × 2.5, 5 s Jumper type : Max. overload current, 5 s	
Resistance to soldering heat	±1 %	100 m Ω or less	270 ℃, 10 s	
Rapid change of temperature	±1 %	100 m Ω or less	–55 ℃ (30min.)/+155 ℃ (ERJU0X,U01 : +125 ℃) (30min.), 100 cycles	
High temperature exposure	±1 %	100 m Ω or less	+155 ℃ (ERJU0X,U01 : +125 ℃), 1000 h	
Damp heat, Steady state ±1 % 100 mΩ or less 60 °C, 90 % to 95		60 ℃, 90 % to 95 %RH, 1000 h		
Load life in humidity	±3 %	100 m Ω or less	60 ℃, 90 % to 95 %RH, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h	
Endurance at 70 ℃	±3 %	100 m Ω or less	70 ℃, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h	

• ERJ U6S, U6Q series

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±1 %	Rated voltage × 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +125 ℃ (30min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

53

Panasonic INDUSTRY

Anti-Sulfurated Thick Film Chip Resistors (Precision Type)



ERJ U R type (Ag-Pd-based inner electrode type) ERJ U2R, U3R, U6R series

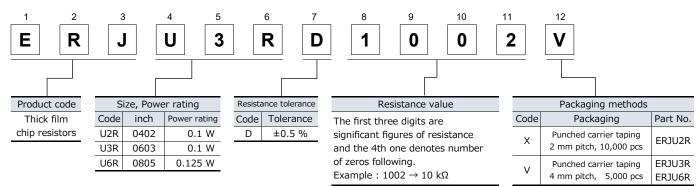
Features

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode.
- High precision : Resistance tolerance : $\pm 0.5 \%$, TCR : $\pm 50 \times 10^{-6}$ /K
- High reliability : Metal glaze thick film resistive element and three layers of electrodes.
- Suitable for both reflow and flow soldering.
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

ERJ U2R, U3R, U6R series



Ratings Power Limiting Maximum Category AEC-Resistance Part No. element overload Resistance range T.C.R. rating^{*1} temperature tolerance Q200 (inch size) (70 ℃) voltage^{*2} voltage^{*3} (Ω) $(\times 10^{-6}/K)$ range (%) Grade (°C) (W) (V)(V)ERJU2R 100 to 100 k 0.1 50 100 ±0.5 (E24, E96) (0402) ERJU3R 100 to 100 k 0.1 75 150 ±0.5 ± 50 -55 to +155 Grade 0 (E24, E96) (0603) ERJU6R 100 to 100 k 0.125 150 200 ± 0.5 (E24, E96) (0805)

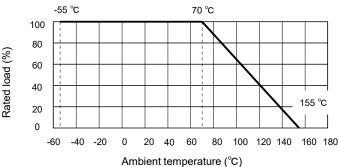
*1 : Use it on the condition that the case temperature is below the upper category temperature.

*2 : Rated continuous working voltage (RCWV) shall be determined from RCWV= $\sqrt{Power rating \times Resistance value}$,

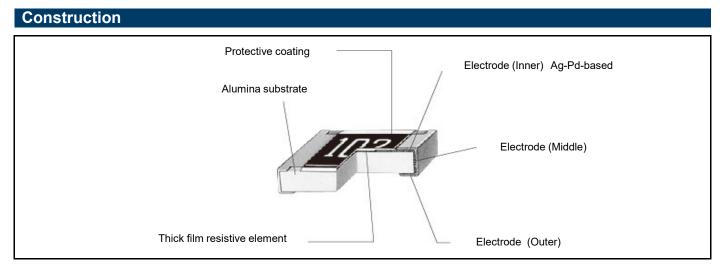
or limiting element voltage listed above, whichever less. *3 : Overload test voltage (OTV) shall be determined from OTV = Specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.

Power derating curve

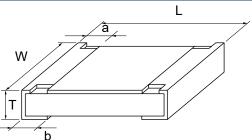
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Anti-Sulfurated Thick Film Chip Resistors (Precsion Type)



Dimensions (not to scale)



	Dimensions							
Part No.	L	W	а	b	Т	 (Reference) (g/1000 pcs) 		
ERJU2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.10	0.35±0.05	0.8		
ERJU3R	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2		
ERJU6R	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4		

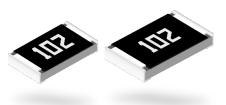
Performance

Test Item	Performance requirements ⊿R	Test conditions			
Resistance	Within specified tolerance	20 ℃			
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃			
Overload	±2 %	Rated voltage × 2.5, 5 s			
Resistance to soldering heat	±1 %	270 ℃, 10 s			
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles			
High temperature exposure	±1 %	+155 ℃, 1000 h			
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h			
Load life in humidity	±2 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 $^\circ \!$	±2 %	70 °C, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			

Panason

INDUSTRY

Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)



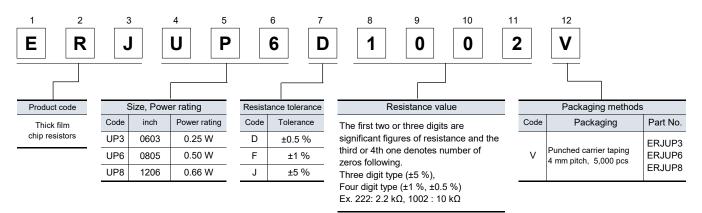
ERJ UP type ERJ UP3, UP6, UP8 series

Features

- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure
- ESD surge characteristics superior to standard metal film resistors
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- 0.25 W : 0603 inch / 1608 mm size (ERJUP3) • High power
 - 0.50 W: 0805 inch / 2012 mm size (ERJUP6)
 - 0.66 W : 1206 inch / 3216 mm size (ERJUP8)
- : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C Reference standard
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Ratings

Part No. (inch size)	Power rating*1 (70 ℃) (W)	Limiting element voltage*2 (V)	Maximum overload voltage*3 (V)	Resistance tolerance (%)	Resistar range (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade				
ERJUP3	0.25	150	200	±0.5, ±1	10 to 1 M ((E24, E96)	±100						
(0603)	0.20	0.25 150	200	±5	1 to 1.5 M	(E24)	±200						
ERJUP6			400 600	±0.5, ±1	10 to 1 M ((E24, E96)	±100	–55 to +155					
(0805)	0.50	400		±5	1 to 3.3 M	(E24)	R<10 Ω : -100 to +600		Grade 0				
(0000)	(0003)				±J	±0	±3	T.0	10	T2	1 10 0.0 10	(L24)	10 Ω≤R ∶±200
				±0.5, ±1	10 to 1 M ((E24, E96)	±100						
	ERJUP8 0.66 (1206)	500	1000	±5	1 to 10 M	(E24)	R<10 Ω : -100 to +600						
(1200)				10		(L24)	10 Ω≤R ∶±200						

*1: Use it on the condition that the case temperature is below the upper category temperature.

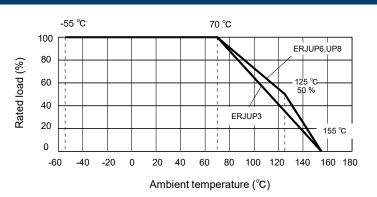
- *2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=/Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- *3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)

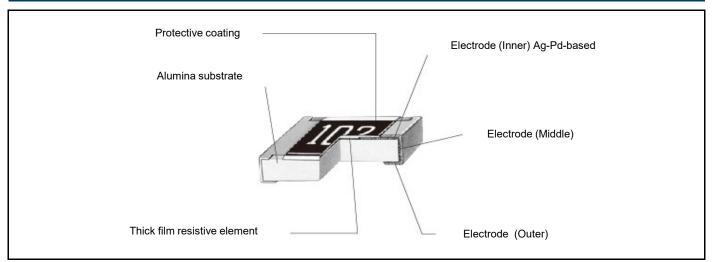
Ratings

Power derating curve

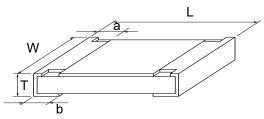
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction

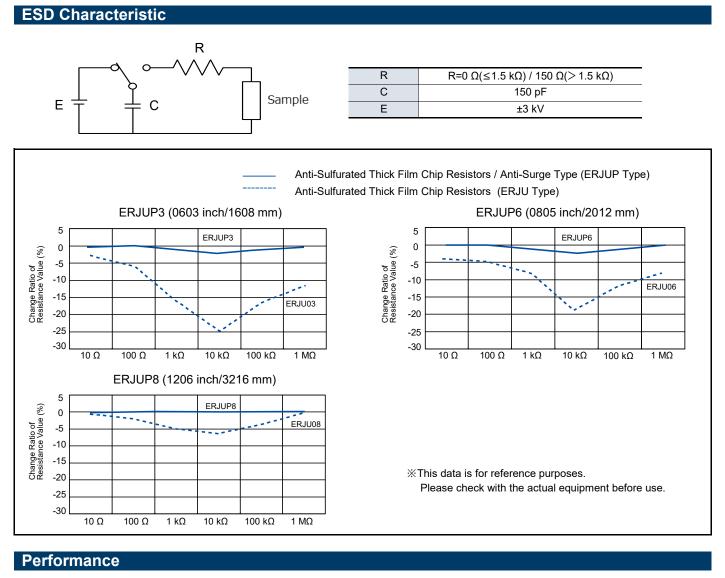


Dimensions in mm (not to scale)



Unit : mm Mass (Weight) Dimensions Part No. (Reference) L W Т а b (g/1000 pcs) ERJUP3 1.60±0.15 0.80+0.15/-0.05 0.15+0.15/-0.10 0.25±0.10 0.45±0.10 2 1.25±0.10 0.60±0.10 ERJUP6 2.00±0.20 0.25±0.20 0.40±0.20 4 ERJUP8 3.20+0.05/-0.20 1.6+0.05/-0.15 0.40±0.20 0.50±0.20 0.60±0.10 10

Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)



Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +155 °C
Overland	+2 %	ERJUP6 : Rated voltag x 1.77, 5 s
Overload	±2 %	ERJUP3, ERJUP8 : Rated voltag x 2.0, 5 s
Resistance to soldering heat	D:±0.5 % F, J:±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change without notice, the subject to change without notice, the subject to contact us immediately. Should a safety concern arise regarding this product, please be sure to contact us immediately. 58

'anason

INDUSTRY

Anti-Sulfurated High Power Chip Resistors (Wide Terminal Type)



ERJ C type

ERJ C1 series

Features

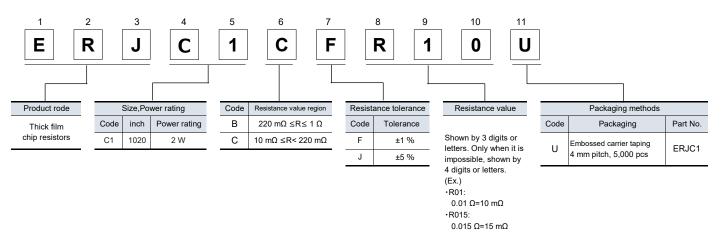
- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure (Covered electrode)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended applications

- Motor control circuit of the industrial equipment
- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems
- Current sensing for power supply circuits in a variety of equipment
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Ratings

Part No. (inch size)	Power rating ^{*1} (70 ℃) (W)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJC1 (1020)	2	±1 10 m to 1 (E24		$\begin{array}{l} 10 \ m\Omega \leq R < 22 \ m\Omega & : \ 0 \ to \ +350 \\ 22 \ m\Omega \leq R < 47 \ m\Omega & : \ 0 \ to \ +200 \\ 47 \ m\Omega \leq R < 100 \ m\Omega & : \ 0 \ to \ +150 \\ 100 \ m\Omega \leq R \leq 1 \ \Omega & : \ \pm100 \end{array}$	–55 to +155	Grade 0
(1020) -		±5		$\begin{array}{l} 10 \ m\Omega \leq R < 22 \ m\Omega & : \ 0 \ to \ +350 \\ 22 \ m\Omega \leq R < 100 \ m\Omega & : \ 0 \ to \ +200 \\ 100 \ m\Omega \leq R \leq 1 \ \Omega & : \ \pm200 \end{array}$		

*1: Use it on the condition that the case temperature is below the upper category temperature.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\/Power Rating × Resistance Value.

· Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW

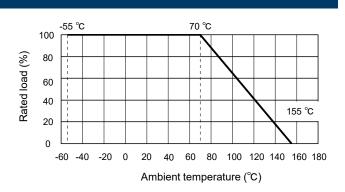
Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use Design and specifications are each subject to change million reaction of the second state of the second st

Anti-Sulfurated High Power Chip Resistors (Wide Terminal Type)

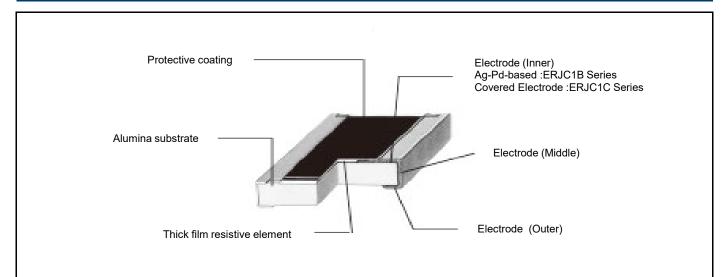
Ratings

Power derating curve

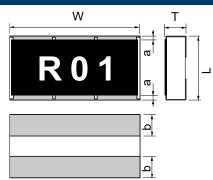
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions (not to scale)



						Unit : mm		
Part No.	Dimensions							
T alt NO.	L	W	а	b	Т	(Reference) (g/1000 pcs)		
ERJC1B	2 50+0 20	5 00+0 20	0.35±0.20	0.90±0.20	0.55±0.20	27		
ERJC1C	2.3010.20	2.50±0.20 5.00±0.20		0.9010.20	0.3310.20	21		

Circuit configuration

*6*0

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

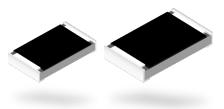
Anti-Sulfurated High Power Chip Resistors (Wide Terminal Type)

Performance		
Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	Rated voltage × 2.0, 5 s
Resistance to soldering heat	±1 %	270 °C, 10 s
Rapid change of temperature	±2 %	–55 ℃ (30 min.) / +125 ℃ (30 min.), 1000 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 °C, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Panasonic

INDUSTRY

High Temperature Thick Film Chip Resistor



(Automotive Grade) ERJH type

ERJ H2G, H2C, H2R, H3G series ERJ H3E, H3Q, H6G, HP6 series

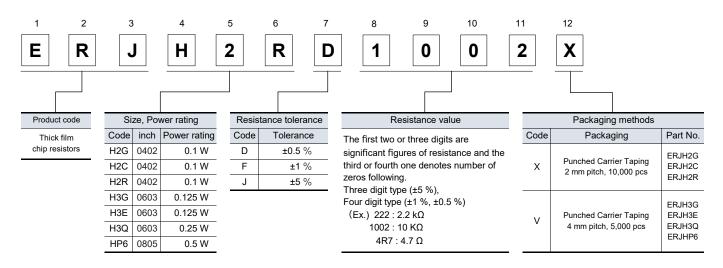
Features

- High reliability : Metal glaze thick film resistive element and high temperature of electrodes structure
- ullet Achieve maximum category temperature 175 $^\circ\!\!C$ and rated category temperature 105 $^\circ\!\!C$
- Compatible with placement machines : Taping packaging available
- Suitable for both reflow and flow soldering
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

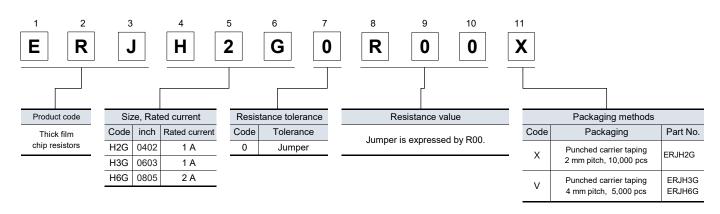
Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

• ERJ H2G, H2C, H2R, H3G, H3E, H3Q, HP6 series : ±0.5 %, ±1 %, ±5 %



• ERJ H2G, H3G, H6G series : Jumper



High Temperature Thick Film Chip Resistor (Automotive Grade)

Ratings

[For R	esistor]
--------	----------

Part No. (inch size)	Power rating*1 (105 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)		Т.С.R. (×10 ⁻⁶ /К)	Category temperature range (℃)	AEC-Q200 Grade
ERJH2G (0402)	0.1	50	100	±5	1 to 300 k	(E24)	R < 10Ω : −100 to +600 10Ω ≤ R : ±200		
ERJH2C (0402)	0.1	50	100	±1	1 to 9.76	(E24,E96)	-100 to +600		
ERJH2R (0402)	0.1	50	100	±0.5,±1	10 to 300 k	(E24,E96)	±100		
ERJH3G (0603)	0.125	75	150	±5	1 to 300 k	(E24)	R < 10Ω : −100 to +600 10Ω ≤ R : ±200		
ERJH3E (0603)	0.125	75	150	±0.5,±1	10 to 300 k	(E24,E96)	±100		Crede 0
ERJH3Q	0.05			±0.5,±1	1 to 9.76	(E24,E96)	1200	55 to +175	Grade 0
(0603)	0.25	-	-	±5	1 to 9.1	(E24)	±200		
	0.5	400	600	±0.5	10 to 300 k	(E24,E96)	R < 33Ω : ±300		
	0.5	400	000	10.5	10 to 300 k	(E24,E90)	$33\Omega \leq R : \pm 100$		
							R < 10Ω : –100 to +600		
ERJHP6	0.5	400	600	±1	1 to 300 k	(E24,E96)	$10\Omega \le R < 33\Omega : \pm 300$		
(0805)	(0805)					$33\Omega \leq R : \pm 100$			
							R < 10Ω : –100 to +600		
	0.5	0.5 400 600	±5	1 to 300 k	(E24)	10Ω ≤R < 33Ω ∶ ±300			
							$33\Omega \leq R : \pm 100$		

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=/Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

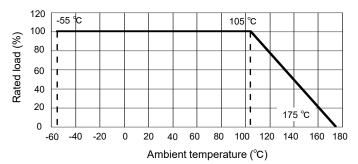
[For Jumper]

_			
Part No. (inch size)	Resistance	Rated current	Maximum overload current ^{*1}
ERJH2G (0402)		1 A	2 A
ERJH3G (0603)	50 m Ω or less	1 A	2 A
ERJH6G (0805)		2 A	4 A

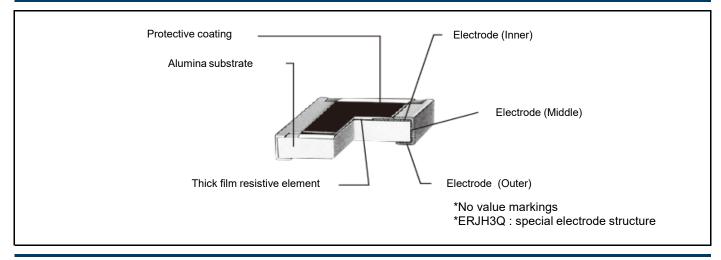
*1: Overload test current

Power derating curve

For resistors operated in ambient temperatures above 105 $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



Construction

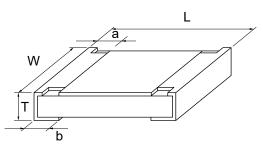


63

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

High Temperature Thick Film Chip Resistor (Automotive Grade)

Dimensions (not to scale)



						Unit : mm		
Part No.	Dimensions							
Fall NO.	L	W	а	b	Т	(Reference) (g/1000 pcs)		
ERJH2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8		
ERJH2C	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8		
ERJH2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8		
ERJH3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2		
ERJH3E	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2		
ERJH3Q	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2		
ERJH6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4		
ERJHP6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4		

Performance

Test item	Performance re	equirements ⊿R	- Test conditions
restitem	Resistor type	Jumper type	
Resistance	Within specified tolerance	50 m Ω or less	20 °C
T. C. R.	Within specified T. C. R.	50 m Ω or less	+25 °C / +175 °C
Overload	±2 %	50 m Ω or less	ERJH2G, H2C, H2R, H3G, H3E, H3Q : Rated voltage× 2.5, 5 s ERJHP6 : Rated voltage× 1.77, 5 s Jumper type : Max. overload current, 5 s
Resistance to soldering heat	±1 %	50 m Ω or less	270 ℃, 10 s
Rapid change of temperature	±1 %	50 m Ω or less	–55 ℃ (30 min.) / +175 ℃ (30 min.), 1000 cycles
High temperature exposure	±1 %	50 m Ω or less	+175 ℃, 1000 h
Damp heat, Steady state	±1 %	50 m Ω or less	85 ℃, 85 %RH, 1000 h
Load life in humidity	±3 %	50 m Ω or less	85 ℃, 85 %RH, Rated voltage (Jumper type :Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 105 ℃	±3 %	50 m Ω or less	105 °C, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

anasor

INDUSTRY

Chip Resistors Array

EXB type



EXB 14V, 18V, 24V, 28V, N8V, 2HV, series EXB 34V, V4V, 38V, V8V, S8V series

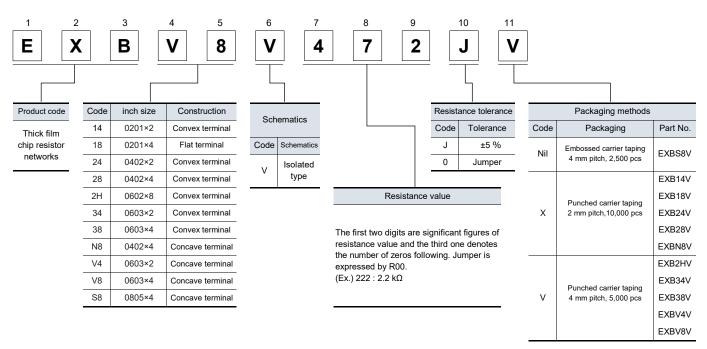
Features

High density

- 2 resistors in 0.8 mm × 0.6 mm size / 0302 inch size : EXB14V
- 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXB18V
- 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXB24V
- 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXB28V, N8V
- 8 resistors in 3.8 mm × 1.6 mm size / 1506 inch size : EXB2HV
- 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXB34V, V4V
- 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXB38V, V8V
- 4 resistors in 5.1 mm × 2.2 mm size / 2009 inch size : EXBS8V
- Improvement of placement efficiency Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor
- : IEC 60115-9, JIS C 5201-9, EIAJ RC-2129 • Reference Standard
- AEC-Q200 compliant (EXB2, EXB3)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Chip Resistors Array

Ratings

[For Resistor]

Part No. (inch size)	Power rating (70 ℃) (W/element)	Limiting element voltage ^{*1} (V)	Maximum overload voltage ^{*2} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (°C)	AEC-Q200 Grade
EXB14V (0201×2)	0.031	12.5	25	±5	10 to 1 M (E24)			
EXB18V (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M (E24)			-
EXB24V (0402×2)	0.063	50	100	±5	1 to 1 M (E24)			
EXB28V (0402×4)	0.063	50	100	±5	1 to 1 M (E24)			
EXB2HV (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M (E24)	R<10 Ω : -200 to +600	-55 to +125	Grade 1
EXB34V (0603×2)	0.063	50	100	±5	1 to 1 M (E24)			
EXB38V (0603×4)	0.063	50	100	±5	1 to 1 M (E24)	: ±200		
EXBN8V (0402×4)	0.031	50	100	±5	10 to 1 M (E24)			
EXBV4V (0603×2)	0.063	50	100	±5	10 to 1 M (E24)			
EXBV8V (0603×4)	0.063	50	100	±5	10 to 1 M (E24)			-
EXBS8V (0805×4)	0.1	100	200	±5	10 to 1 M (E24)			

*1: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= Verver Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

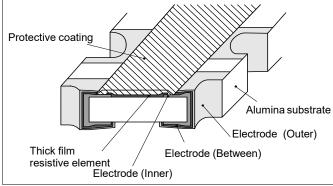
*2: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

[For Jumper]

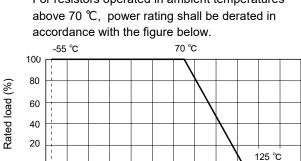
Part No.	Resistance	Rated current	Maximum overload current ^{*1}
EXB14V		0.5 A	1 A
EXB18V		0.5 A	1 A
EXB24V		1 A	2 A
EXB28V	50 m Ω or less	1 A	2 A
EXB2HV		1 A	2 A
EXB34V		1 A	2 A
EXB38V		1 A	2 A
EXBN8V	- · · · · · · · · · · · · · · · · · · ·	1 A	2 A
EXBV4V		1 A	2 A
EXBV8V		1 A	2 A
EXBS8V		2 A	4 A

*1: Overload test current





Power derating curve



60 80 100 120 140 160 180

For resistors operated in ambient temperatures

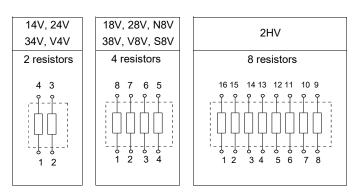
Ambient temperature (°C)

0 20 40

-40 -20

Schematics Isolated type

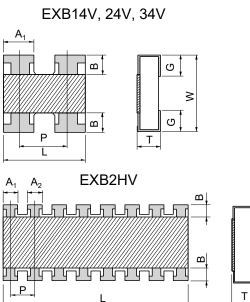
0 -60



Chip Resistors Array

Dimensions (not to scale)

(1) Convex terminal type



EXB28V, 38V A_1 Б шţ П ს ≥ ш വ Т Р

I Init · mm

Part No.	Dimensions								
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(Reference) (g/1000 pcs)
EXB14V (0201×2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10		0.15±0.10	(0.50)	0.15±0.10	0.5
EXB24V (0402×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	_	0.18±0.10	(0.65)	0.25±0.10	1.2
EXB28V (0402×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0
EXB2HV (0602×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0
EXB34V (0603×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5
EXB38V (0603×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0
	•	•	•	·	•	•		•	() Reference

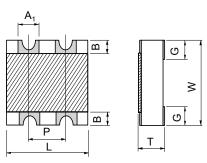
U,

Ъ

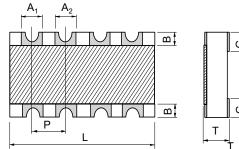
≥

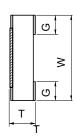
(2) Concave terminal type





EXBN8V, V8V, S8V



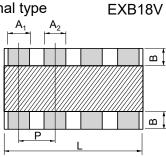


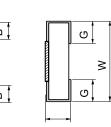
Part No.	Dimensions								Unit : mm Mass (Weight)
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(Reference) (g/1000 pcs)
EXBN8V (0402×4)	2.00±0.10	1.00±0.10	0.45±0.10	0.30±0.10	0.30±0.10	0.20±0.15	(0.50)	0.30±0.15	3.0
EXBV4V (0603×2)	1.60 +0.20/-0.10	1.60 +0.20/-0.10	0.60±0.10	0.60±0.10	—	0.30±0.15	(0.80)	0.45±0.15	5.0
EXBV8V (0603×4)	3.20 +0.20/-0.10	1.60 +0.20/-0.10	0.60±0.10	0.60±0.10	0.60±0.10	0.30±0.15	(0.80)	0.45±0.15	10
EXBS8V (0805×4)	5.08 +0.20/-0.10	2.20 +0.20/-0.10	0.70±0.20	0.80±0.15	0.80±0.15	0.50±0.15	(1.27)	0.55±0.15	30
									() Reference

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change without house. Our racio, i.e. and a subject to change without hour racio, i.e. and a subject to change without house. Our

Dimensions (not to scale)

(3) Flat terminal type





Unit : mm

Part No.	Dimensions							Mass (Weight) (Reference)	
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(g/1000 pcs)
EXB18V (0201×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0

() Reference

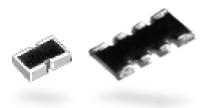
Performance

Test Item	Performance requirements ⊿R	Test conditions	
Resistance	Within specified tolerance	20 °C	
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C	
Overload	±2 %	Rated voltage x 2.5,5 s Jumper type:Max. overload current, 5 s	
Resistance to soldering heat	±1 %	270 ℃, 10 s	
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.),100 cycles	
High temperature exposure	±1 %	+125 ℃, 1000 h	
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h	
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h	
Endurance at 70 °C ±3 %		70 ℃, Rated voltage (Jumper type :Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h	

Panasonic

INDUSTRY

Anti-Sulfurated Chip Resistors Array



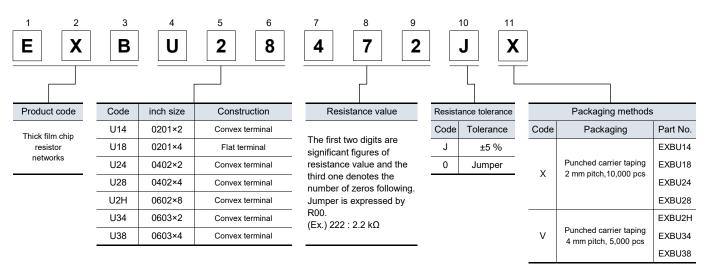
EXB type EXB U14, U18, U24, U28 series EXB U2H, U34, U38 series

Features

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode
- High density
 - 2 resistors in 0.8 mm × 0.6 mm size / 0302 inch size : EXBU14
 - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXBU18
 - 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXBU24
 - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXBU28
 - 8 resistors in 3.8 mm × 1.6 mm size / 1506 inch size : EXBU2H
 - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXBU34
 - 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXBU38
- Improvement of placement efficiency
 Placement efficiency of chip resistor array is two, four or eight times of the flat type chip resistor
- Reference standard : IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- AEC-Q200 compliant (EXBU2, EXBU3)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Anti-Sulfurated Chip Resistors Array

Ratings

[For Resistor]

Part No. (inch size)	Power rating (70 ℃) (W/element)	Limiting element voltage ^{*1} (V)	Maximum overload voltage ^{*2} (V)	Resistance tolerance (%)	Resistar range (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
EXBU14 (0201×2)	0.031	12.5	25	±5	10 to 1 M	(E24)			
EXBU18 (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M	(E24)	R<10 Ω : -200 to +600 - 10 Ω to 1 MΩ : ±200		
EXBU24 (0402×2)	0.063	50	100	±5	1 to 1 M	(E24)			
EXBU28 (0402×4)	0.063	50	100	±5	1 to 1 M	(E24)		-55 to +125	
EXBU2H (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M	(E24)			Grade 1
EXBU34 (0603×2)	0.063	50	100	±5	1 to 1 M	(E24)			
EXBU38 (0603×4)	0.063	50	100	±5	1 to 1 M	(E24)			

*1: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\/Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

*2: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

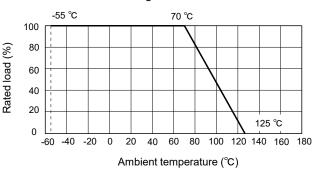
[For Jumper]

Part No.	Resistance	Rated current	Maximum overload current ^{*1}					
EXBU24								
EXBU28								
EXBU2H	100 m Ω or less	1 A	2 A					
EXBU34								
EXBU38								
*4. Opender all the strengen st								

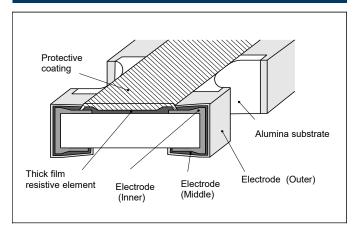
*1: Overload test current

Power derating curve

For resistors operated in ambient temperatures above 70°C, power rating shall be derated in accordance with the figure below.

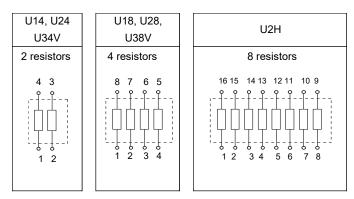


Construction



Schematics

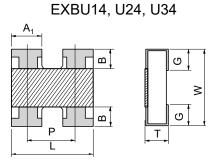
Isolated type



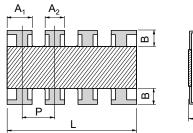
Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change management of the second state of the second se

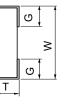
Anti-Sulfurated Chip Resistors Array

Dimensions (not to scale)

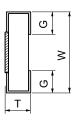


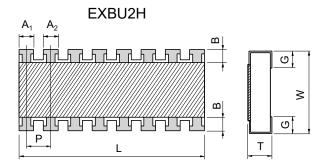
EXBU28, U38





EXBU18 A_1 A_2 шţ <u>ш</u> P I





Part No.				nsions	sions					
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(Reference) (g/1000 pcs)	
EXBU14 (0201X2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	—	0.15±0.10	(0.50)	0.15±0.10	0.5	
EXBU18 (0201×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0	
EXBU24 (0402×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	—	0.18±0.10	(0.65)	0.25±0.10	1.2	
EXBU28 (0402×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0	
EXBU2H (0602×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0	
EXBU34 (0603×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5	
EXBU38 (0603×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0	

() Reference

Performance		
Test Item	Performance	Test conditions
	requirements ⊿R Within specified	
Resistance	tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C / +125 °C
Overload	±2 %	Rated voltage x 2.5, 5 s
Resistance to soldering heat	±1 %	Jumper type : Max. overload current, 5 s 270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +125 ℃ (30 min.),100 cycles
High temperature exposure	±1 %	+125 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70℃	±3 %	70℃, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h

Design and specifications are each subject to change without house, i.e., sector, should a safety concern arise regarding this product, please be sure to contact us immediately. 71 Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Panasonic INDUSTRY

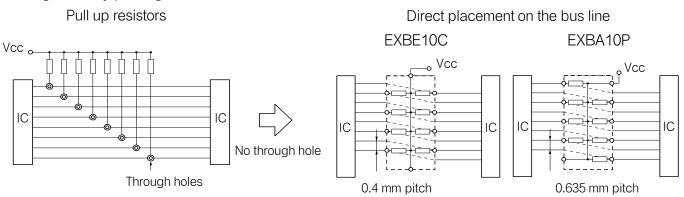
Chip Resistors Networks EXB type EXB D, E, A, Q series



Features

- High density placing for digital signal circuits
 - ·Bussed 8 or 15 resistors for pull up/down circuits
 - EXBD : 3.2 mm × 1.6 mm × 0.55 mm, 0.635 mm pitch
 - EXBE : 4.0 mm × 2.1 mm × 0.55 mm, 0.8 mm pitch
 - : 6.4 mm × 3.1 mm × 0.55 mm, 1.27 mm pitch EXBA
 - : 3.8 mm × 1.6 mm × 0.45 mm, 0.5 mm pitch EXBQ
 - · Available direct placing on the bus line by means of half pitch spacing without through-holes on PWB ("High density placing" is shown below)
- High speed mounting using conventional placing machine
- Reference Standard : IEC 60115-9, JIS C 5201-9, EIAJ RC-2130
- RoHS compliant

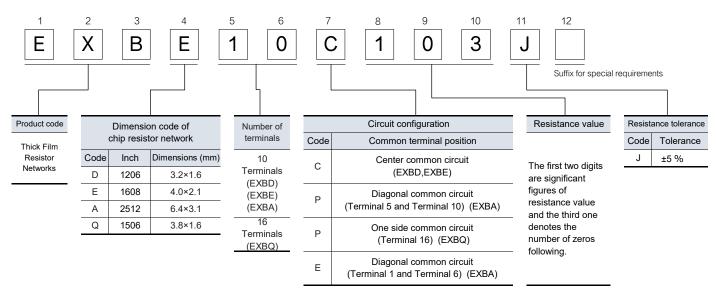
[High density placing]



As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use Design and specifications are each subject to charge mutual nearest interest of the specification of the specifica

Chip Resistors Networks

Ratings

Part No. (inch size)	Resistance range (Ω)	Resistance tolerance (%)	Number of terminals	Number of resistors	Power rating ^{*1} (70 ℃) (W/element)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
EXBD (1206)			±5 10 terminals 16 terminals	8 element	0.05 / element	25	50	±200		
EXBE (1608)	47 to 1 M (E12)				0.063 / element	25	50	±200	55 to +125	
EXBA (2512)	BA	10			0.063 / element	50	100	±200		-
EXBQ (1506)	100 to 470 k (E6)			15 element	0.025 / element	25	50	±200		

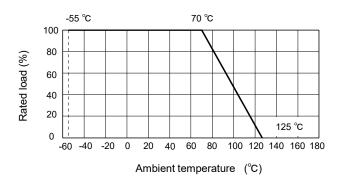
*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

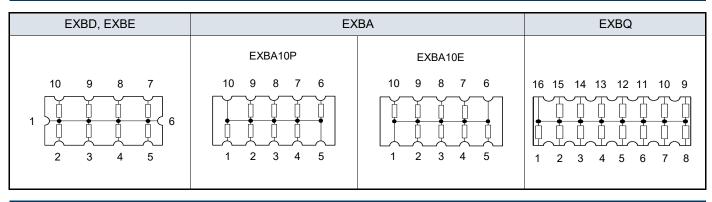
Power derating curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



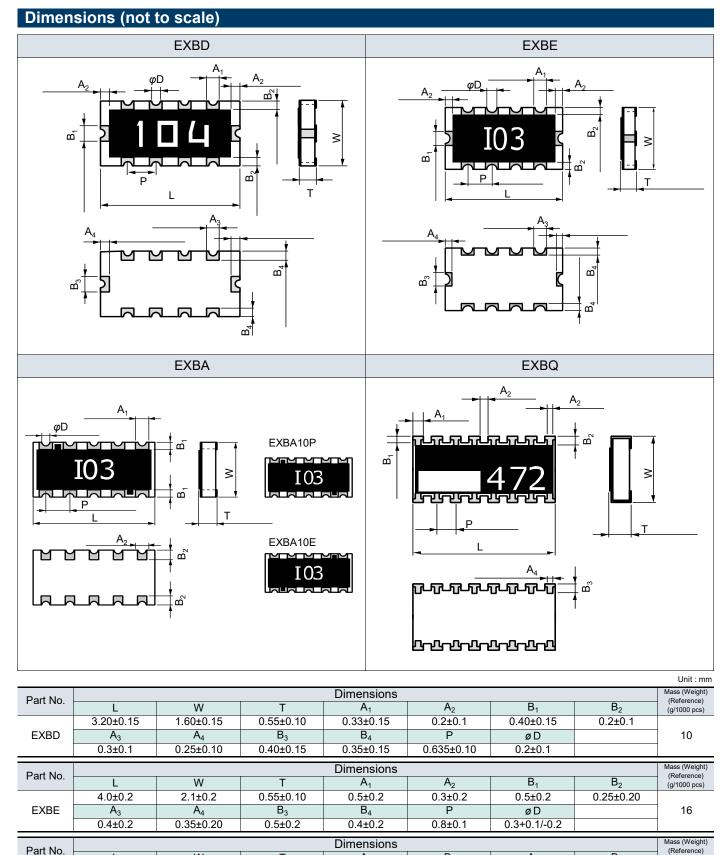
Construction (Example : EXBD) Protective coating Protective coating Electrode (Inner) Alumina substrate Electrode (Outer) Thick film Thick film resistive element Alumina substrate Electrode resistive element Electrode (Middle) (Inner)

Circuit configuration



Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change without nearest, should a safety concern arise regarding this product, please be sure to contact us immediately. 73

Chip Resistors Networks



	L	W	Т	A ₁	B ₁	A ₂	B ₂	(g/1000 pcs)			
	6.4±0.2	3.1±0.2	0.55±0.10	0.7±0.2	0.3±0.2	0.5±0.2	0.5±0.20				
EXBA	Р	øD						40			
	1.27±0.10	0.3+0.1/-0.2									
Part No.	Dimensions										
Part No.	L	W	Т	A ₁	A ₂	A ₃	B ₁	 (Reference) (g/1000 pcs) 			
	3.8±0.2	1.6±0.2	0.45±0.10	0.3±0.1	0.2±0.1	0.15+0.15/-0.05	0.15+0.15/-0.05				
EXBQ	B ₂	A ₄	B ₃	Р				9			
	0.25±0.15	0.15+0.20/-0.05	0.30±0.15	0.5±0.1							

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to charge without reaction and specifications are each subject to charge without reaction and the specification of the specification o

Chip Resistors Networks

Performance							
Test Item	Performance requirements ⊿R	Test conditions					
Resistance	Within specified tolerance	20 °C					
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C					
Overload	±3 %	Rated voltage x 2.5, 5 s					
Resistance to soldering heat	±1 %	260 °C ±5 °C, 5 s ±1 s					
Rapid change of temperature	±2 %	–55 ℃ (30 min.) / +125 ℃ (30 min.),5 cycles					
High temperature exposure	±3 %	+125 ℃, 100 h					
Load life in humidity	±3 %	60 ℃±2 ℃, 90 % to 95 %RH, Rated power × 0.1, 1.5 h ON / 0.5 h OFF cycle, 500 h					
Endurance at 70 ℃	±5 %	70 ℃±2 ℃,Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h					

'anasoi INDUSTRY

Chip Attenuator EXB type



EXB 14AT, 24AT series

Features

- Unbalanced π type attenuator circuit in one chip EXB14AT (0.8 mm×0.6 mm), EXB24AT (1.0 mm×1.0 mm)
- Reduced mounting area

EXB14AT : About 60 % smaller than the area of an attenuator circuit consisting of three 0603 chip resistors, almost equal to the area of three 0402 chip resistors

EXB24AT : About 50 % smaller than the area of an attenuator circuit consisting of three 1005 chip resistors, almost equal to the area of three 0603 chip resistors

- Mounting cost reduction : (Only 1 chip placed as compared to 3)
- Attenuation : 1 dB to 10 dB

RoHS compliant

Recommended applications

- Attenuation / level control / impedance matching of high frequency (communication signalling equipment cellular phones(GSM, CDMA, PDC, etc.), PHS, PDAs)
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

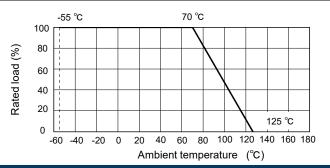
Explanation of part numbers Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below. 7 1 2 3 5 6 8 9 10 12 4 11 Ε Х B 1 4 Α Т 3 R 3 Х Α Product code Dimensions and circuit Attenuation value Characteristics Tolerance Packaging methods Code configuration One-digit number /one impedance R3 ±0.3 dB Code Packaging Thick film (π type attenuator) letter shows 50 Ω R5 ±0.5 dB resistor Α Punched carrier taping networks 0.8 mm × 0.6 mm attenuation value Х 14AT 2 mm pitch, 10,000 pcs (inch size : 0302) (Ex.) 1.0 mm × 1.0 mm $1 \rightarrow 1 \text{ dB}, \text{ A} \rightarrow 10 \text{ dB}$ 24AT (inch size : 0404)

Ratings	
Part No.	EXB14AT, EXB24AT
Attenuation value	1 dB, 2 dB, 3 dB, 4 dB, 5 dB, 6 dB, 10 dB*
Attenuation value tolerance	1 dB, 2 dB, 3 dB, 4 dB, 5dB : ±0.3 dB
Allendation value tolerance	6 dB, 10 dB:±0.5 dB
Characteristic impedance	50 Ω
Power rating at 70 ℃	0.04 W / package
Frequency range	DC to 3.0 GHz
VSWR (Voltage standing wave ratio)	1.3 max.
Number of resistors	3 resistors
Number of terminals	4 terminals
Category temperature range	–55 ℃ to +125 ℃

* Please inquire about the other Attenuator value

Power derating curve

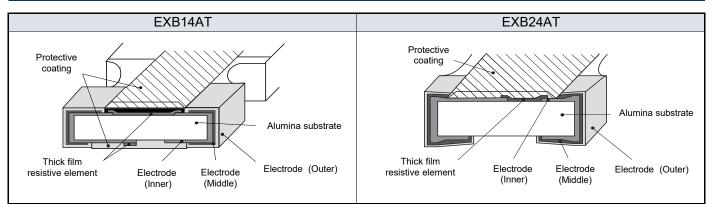
For resistors operated in ambient temperatures above 70 ℃, power rating shall be derated in accordance with the figure on the right.



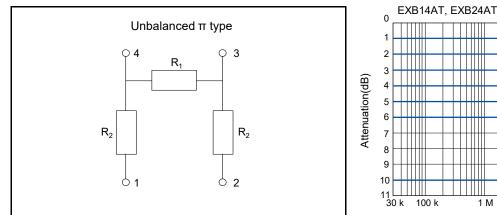
Design and specifications are each subject to charge managements. Should a safety concern arise regarding this product, please be sure to contact us immediately. 76 Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use

Chip Attenuator

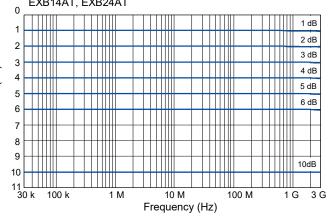
Construction



Circuit configuration

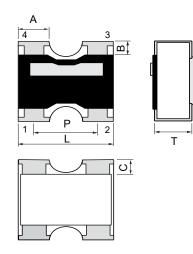


Attenuation-frequency characteristics

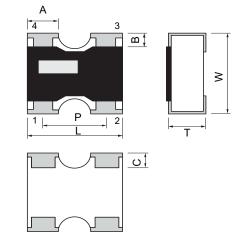


Dimensions (not to scale)

EXB14AT



EXB24AT



< Marking Configuration>

The bar marking for recognizing terminal direction is located on the side of terminal 3, 4.

< Marking Configuration>

The bar marking for recognizing terminal direction is located on the side of terminal 4.

								Unit : mm			
Part No.	Dimensions										
Fait NO.	L	W	Т	A	В	С	P (typical value)	(Reference) (g/1000 pcs)			
EXB14AT	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	0.15±0.10	0.15±0.10	0.50	0.7			
EXB24AT	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	0.15±0.10	0.25±0.10	0.65	1.1			

	 1	
	met	

Surfac	e mount resistors series			Packaging (Standar	d quantity : pcs/reel)	
		0.	Pressed	Punched	Punched	Embossed
Products	Part No.	Size (mm) (inch)	carrier taping	carrier taping	carrier taping	carrier tapino
			(2 mm pitch)	(2 mm pitch)	(4 mm pitch)	(4 mm pitch
	ERJXGN	0402 (01005)	20,000 ^{*1}	—	_	40,000 ^{*2}
	ERJ1GN	0603 (0201)	15,000	—	—	
	ERJ2GE	1005 (0402)	—	10,000	—	
	ERJ3GE	1608 (0603)	_		5,000	—
Thick film	ERJ6GE	2012 (0805)	_		5,000	—
chip resistors	ERJ8GE	3216 (1206)			5,000	
	ERJ14	3225 (1210)	_		_	5,000
	ERJ12	4532 (1812)			_	5,000
	ERJ12Z	5025 (2010)			_	5,000
	ERJ1T	6432 (2512)				4,000
	ERJXGN	0402 (01005)	20,000 ^{*1}		_	40,000 ^{*2}
	ERJ1GN/1RH	0603 (0201)	15,000			
chip resistors Precision thick film chip resistors Metal film (Thin film) chip resistors, tigh reliability type Thick film chip resistors/ ow resistance type Current sensing resistors,	ERJ2RC/2RH/2RK	1005 (0402)	_	10,000	_	
	ERJ3RB/3RE/3EK	1608 (0603)	_		5,000	
	ERJ6RB/6RE/6EN	2012 (0805)			5,000	_
	ERJ8EN	3216 (1206)			5,000	
	ERJ14N	3225 (1210)				5,000
	ERJ12N	4532 (1812)				5,000
-	ERJ12S					5,000
	ERJ1TN					4,000
	ERA1A		15,000			
Metal film	ERA2A/2V			10,000		
(Thin film) chip resistors,	ERA3A/3V/3K		_		5,000	
	ERA6A/6V/6K				5,000	
	ERA8A/8V/8K/8P				5,000	
	ERJ2LW/2BW		10.000			
chip resistors Precision thick film chip resistors Metal film (Thin film) chip resistors, High reliability type Thick film chip resistors/ ow resistance type Current sensing resistors, Metal plate type High power chip resistors/ Wide terminal type High precision thick				10,000		
			_		5,000	
	ERJ6L/6B/6C				5,000	
		. ,			•	
Thick film chip resistors Precision thick film chip resistors Metal film (Thin film) chip resistors, High reliability type Thick film chip resistors/, ow resistance type Current sensing resistors, Metal plate type High power chip resistors/ Wide terminal type High precision thick film chip resistors				—	5,000	
			—		—	5,000
			—		_	5,000
						5,000
Current sensing						4,000
					—	2,000
	ERJMB1	2550 (1020)		—		3,000
		3264 (1225)		—		4,000
Precision thick film chip resistors ERJ1GN/1RH 0603 (0201) 15,000 ERJ2RC/2RH/2RK 1005 (0402) - 100 ERJ3RB/3RE/3EK 1608 (0603) - 100 ERJ12N 4532 (1812) - 100 ERJ12N 4532 (2512) - 100 ERJ12N 6432 (2512) - 100 ERJ12N 6432 (2512) - 100 ERJ12N 6432 (2512) - 100 Metal film (Thin film) chip resistors, High reliability type ERA4A/2V 1005 (0402) - 100 ERA8A/8V/8K/8P 3216 (1206) - 100 100000 100,000 ERJ2BS/2BQ 1005 (0402) - 100 100 100 Low resistance type ERJ8B/8C/8R/L08 3		2550 (1020)	_	_	—	5,000
		1632 (0612)			5,000	
		5,000				
ligh precision thick					5,000	
					5,000	

*1: W8P2 : Width 8 mm, Pitch 2 mm,

*3: Anti-Sulfurated High power chip resistors / Wide terminal type

*2: W4P1 : Width 4 mm, Pitch 1 mm

*4: Low TCR High power chip Resistors / Wide terminal type

Packaging method

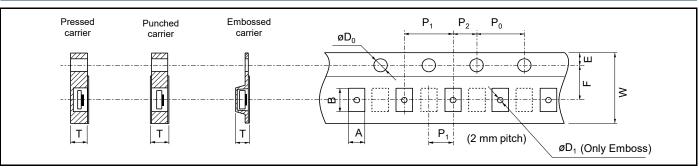
Surfac	e mount resistors serie	S		Packaging (Standar	d quantity : pcs/reel)	
		0.	Pressed	Punched	Punched	Embossed
Products	Part No.	Size (mm) (inch)	carrier taping	carrier taping	carrier taping	carrier taping
			(2 mm pitch)	(2 mm pitch)	(4 mm pitch)	(4 mm pitch
	ERJPA2	1005 (0402)	_	10,000		_
	ERJP03/PA3	1608 (0603)	_	_	5,000	
nti-Surge Thick film	ERJP06/P6W	2012 (0805)	_	_	5,000	
chip resistors	ERJP08/PM8	3216 (1206)	_	_	5,000	_
	ERJP14	3225 (1210)		_		5,000
	ERJT06	2012 (0805)		_	5,000	
Anti-Pulse Thick	ERJT08	3216 (1206)			5,000	
film chip resistors	ERJT14	3225 (1210)		_		5,000
	ERJU0X	0402 (01005)	20,000	_	_	
	ERJU01	0603 (0201)	15,000			
	ERJS02/U02	1005 (0402)		10,000		
	ERJS03/U03	1608 (0603)			5,000	
Anti-Sulfurated Thick film	ERJS06/U06 ERJU6S/U6Q	2012 (0805)		_	5,000	_
chip resistors	ERJS08/U08	3216 (1206)			5,000	
	ERJS14/U14	3225 (1210)		_	, - 	5,000
	ERJS12/U12	4532 (1812)		_		5,000
-	ERJS1D/U1D	5025 (2010)				5,000
-	ERJS1T/U1T	6432 (2512)				4,000
	ERJU2R	1005 (0402)		10,000		
Anti-Sulfurated hick film chip resistors /	ERJU3R	1608 (0603)			5,000	
Precision type	ERJU6R	2012 (0805)			5,000	
	ERJUP3	1608 (0603)			5,000	
Anti-Sulfurated Thick film chip resistors / Anti-Surge type	ERJUP6	2012 (0805)			5,000	
	ERJUP8	3216 (1206)			5,000	
	ERJH2G/2C/2R	1005 (0402)		10,000	0,000	
High temperature thick	ERJH3G/3E/3Q	1608 (0603)			5,000	
	ERJH6G/HP6	2012 (0805)			5,000	
	EXB14V	0806 (0302)		10,000		
·	EXB24V	1010 (0404)		10,000		
-	EXB34V	1616 (0606)			5,000	
-	EXBV4V	1616 (0606)			5,000	
-	EXB18V	1406 (0502)		10,000	3,000	
Chip resistor	EXB28V	2010 (0804)		10,000		
array	EXBN8V	2010 (0804)		10,000		
-	EXB38V	3216 (1206)			5,000	
-	EXBV8V	3216 (1206)			5,000	
-	EXBS8V	5022 (2009)			3,000	2,500
-	EXB2HV	3816 (1506)			5,000	2,500
	EXBU14	0806 (0302)		10,000	3,000	
-	EXBU18	1406 (0502)		10,000		
·	EXBU24	1010 (0404)		10,000		
Anti-Sulfurated	EXBU34	1616 (0606)		10,000	5,000	
chip resistor array	EXBU28	2010 (0804)		10,000	5,000	
ŀ	EXBU38	3216 (1206)		10,000	5,000	
ŀ	EXBU38 EXBU2H	3816 (1200)				
					5,000	—
ŀ	EXBD	3216 (1206)			5,000	4.000
hip resistor networks	EXBE	4021 (1608)	—	—	—	4,000
ŀ	EXBA	6431 (2512)			—	4,000
	EXBQ	3816 (1506)	—	—	5,000	—
Chip attenuator	EXB14AT	0806 (0302)	—	10,000		—
	EXB24AT	1010 (0404)	—	10,000	—	—

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without notice, not receive and the subject to change without not receive and the subje

Panasonic INDUSTRY

Surface Mount Resistors Packaging Method (Taping)

Carrier tape



Pressed carrier taping (2 mm Pitch)

Chip resistors / Precision chip / Metal film(Thin film)chip / Low resistance / Anti-Sulfurated											
Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
ERJXGN ERJU0X	0402 (01005)	0.24±0.03	0.45±0.03								0.31±0.05
ERJ1GN ERJ1R ERJU01 ERA1A	0603 (0201)	0.38±0.05	0.68±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.42±0.05
ERJ2LW	1005 (0402)	0.68±0.10	1.20±0.10								0.60±0.05
ERJ2BW	1003 (0402)	0.67±0.10	1.17±0.10								0.61±0.05

Punched	Punched carrier taping (2 mm Pitch)										
Chip resistors / Precision chip / Thin film chip / Low resistance / Anti-Surge / Anti-Sulfur / High temperature / Metal foil type											Unit : mm
Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
ERJ2 ERJPA2 ERJ2 ERJ2 ERJ2 ERA2	1005 (0402)	0.67±0.05	1.17±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.52±0.05

• Chip resistor array / Anti-Sulfurated chip resistor Aarray / Chip attenuator

Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
EXB14V EXB14AT	0806 (0302)	0.70 +0.10/-0.05	0.95 +0.05/-0.10								
EXB18V	1406 (0502)		1.60±0.10								
EXB24V EXBU24 EXB24AT	1010 (0404)	1.20±0.10	1.20±0.10	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.52±0.05
EXB28V EXBU28 EXBN8V	2010 (0804)		2.20±0.10								

Punched carrier taping (4 mm Pitch)

Chip resistors / Precision chip / Metal film(Thin film)chip / Low resistance / High power / High precision / Anti-Surge /

Anti-Pulse /	Anti-Sulfurate	d / High tem	perature						-		Unit : mm
Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
ERJ3 ERJ3LW(10mΩ) ERJ3BW ERJ 3 ERJ 3 ERA3	1608 (0603)	1.10±0.10	1.90±0.10								0.70±0.05
ERJ3LW(5mΩ)											
ERJ6 ERJ ERJ6 ERA6 ERA6	2012 (0805)	1.65±0.15	2.50±0.20	8.00±0.20	3.50±0.05	1.75±0.10	4.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.84±0.05
ERJB3	1220 (0508)										
ERJ6BW ERJ6LW ERJ6CW	2012 (0805)	1.55±0.15	2.30±0.20								0.94±0.05
ERJ8 ERJ8 W ERJ 8 ERA8	3216 (1206)	2.00±0.15	3.60±0.20								0.84±0.05
ERJB2 ERJD2	1632 (0612)										

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Should a safety concern arise regarding this product, please be sure to contact us immediately.

Unit : mm

Surface Mount Resistors Packaging Method (Taping)

Punche	d carrier t	aping (4 mm P	itch)							
 Chip resist 	or array / Anti-S	Sulfurated cl	nip resistor a	array / Chip	resistor net	works					Unit : mm
Part No.	Size (inch)	А	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
EXB34V EXBU34	1616 (0606)		1.95±0.20								
EXB38V EXBU38	3216 (1206)		3.60±0.20	8.00±0.20							0.70±0.05
EXB2HV EXBU2H	3816 (1506)	1.95±0.15	4.10±0.15		3.50±0.05	1.75±0.10	0 4.00±0.10	0 2.00±0.05	5 4.00±0.10) 1.50 +0.10/0	
EXBV4V	1616 (0606)										0.84±0.05
EXBV8V	3216 (1206)		3.60±0.20								0.0410.05
EXBD	3216 (1206)	2.00±0.20	3.60±0.20								0.84±0.10
EXBQ	3816 (1506)	1.90±0.20	4.10±0.20								0.64±0.05
	•	•			•	•					

Embossed carrier taping (1 mm Pitch)

Chip resist	ors										Unit : mm
Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
ERJXGN	0402 (01005)	0.25±0.05	0.45±0.05	4.00±0.20	1.80±0.05	0.90±0.10	1.00±0.10	1.00±0.10	2.00±0.10	0.80±0.10	0.5 max.

Embossed carrier taping (4 mm Pitch)

• Chip resistors / Precision chip / Low resistance / High power / Anti-Surge / Anti-Pulse / Anti-Sulfurated

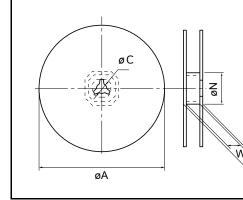
 Chip resis 	tors / Precision	chip / Low r	resistance /	High power	/ Anti-Surge	e / Anti-P	ulse / An	ti-Sulfura	ted			Unit : mm
Part No.	Size (inch)	А	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т	øD ₁
ERJ14 ERJ□14	3225 (1210)	2.80±0.20	3.50±0.20	8.00±0.30	3.50±0.05							1.00+0.10/0
ERJ12 ERJ□12	4532 (1812)	3.50±0.20	4.80±0.20									
ERJ12Z ERJ12S ERJ□1D	5025 (2010)	- 2.80±0.20	5 2010 20			1.75	4.00	2.00	4.00	1.50	1.00±0.10	
ERJB1 ERJC1 ERJD1	2550 (1020)	2.80±0.20	5.30±0.20	12.00 ±0.30	5.50±0.20	±0.10	±0.10	±0.05	±0.10	+0.10/0		1.5 min.
ERJ1T ERJ 1T ERJL1W	6432 (2512)	3.60±0.20	6.90±0.20								1.60±0.10	
ERJA1	3264 (1225)	3.50±0.20	6.80±0.20	-							1.10±0.20	

• Current sensing resistors, Metal plate type

 Current ser 	nsing resistors,	Metal plate	type									Unit : mm
Part No.	Size (inch)	А	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т	øD ₁
ERJMB1	2550 (1020)	2.90±0.20	5.40±0.20	12.00 ±0.30	5.50±0.10	1.75	4.00	2.00	4.00	1.50	1.55±0.20	_
ERJMS4	6432 (2512)	3.50±0.20	6.90±0.20	12.00 ±0.30	5.50±0.10	±0.10	±0.10	±0.05	±0.10	+0.10/0	1.60±0.20	1.5 min.

 Chip resist 	or array / Chip I	resistor netv	vorks									Unit : mm
Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т	øD ₁
EXBS8V	5022 (2009)	2.80±0.20	5.70±0.20								1.6 max.	
EXBE	4021 (1608)	2.50±0.20	4.40±0.20	12.00±0.30	5.50±0.20	1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	1.10±0.20	1.5 min.
EXBA	6431 (2512)	3.50±0.20	6.80±0.20			10.10	10.10	10.00	10.10		1.10±0.20	

Taping reel



ape width (W)	øA	øN	øC	W ₁	W ₂
4 mm width	180.0±3.0			4.5±0.5	7.0±0.5
8 mm width	100 0 0/ 1 5	60.0+1.0/0	12.010.0	9.0+1.0/0	11.4±1.0
12 mm width	- 180.0 0/-1.5 380.0±2.0		13.0±0.2	13.0+1.0/0	15.4±1.0
24 mm width	380.0±2.0	80.0±1.0		25.4±1.0	29.4±1.0

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

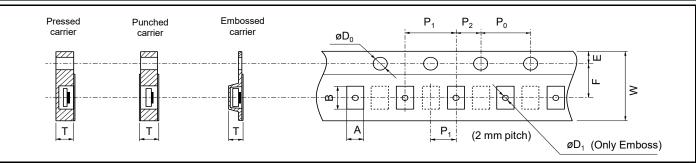
Should a safety concern arise regarding this product, please be sure to contact us immediately.

[Discontinued product]

Packaging method

Surfac	e mount resistors serie	s		Packaging (Standar	d quantity : pcs/reel)	
		Size	Pressed	Punched	Punched	Embossed
Products	Part No.	(mm) (inch)	carrier taping	carrier taping	carrier taping	carrier taping
			(2 mm pitch)	(2 mm pitch)	(4 mm pitch)	(4 mm pitch)
Thick film chip resistors/ Low resistance type	ERJL1W	6432 (2512)	_	_	—	3,000
	ERJMP2	3216 (1206)			_	3,000
Current sensing	ERJMP3	5025 (2010)		_	_	3,000
resistors,	ERJMP4	6432 (2512)		_	_	2,000
Metal plate type	ERJMS6	6468 (2526)	—	—	—	1,000 (8mm Pitch)
	ERJM1W	6432 (2512)	—	—	—	3,000
Current sensing resistors, Metal foil type	ERJMFBA	1005 (0402)	_	10,000	_	_

Carrier tape



Punched carrier taping (2 mm Pitch)

Chip resisto	ors / Precision	chip / Thin f	ilm chip / Lo	w resistanc	e / Anti-Suro	ge / Anti-Sul	fur / High te	mperature /	Metal foil ty	ре	Unit : mm
Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
ERJMFBA	1005 (0402)	0.67±0.05	1.17±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.60±0.05

Embossed carrier taping (4 mm Pitch)

 Chip resistor 	ors / Precision	chip / Low r	esistance / H	High power	Anti-Surge	/ Anti-Pu	ilse / Ant	i-Sulfurat	ed			Unit : mm
Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т	øD ₁
ERJL1W	6432 (2512)	3.60±0.20	6.90±0.20	12.00 ±0.30	5.50±0.20	1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	1.60±0.10	1.5 min.

Part No.	Size (inch)	А	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т	øD ₁
ERJMP2 (1 mΩ)	3216 (1206)										1.55±0.20	_
ERJMP2 (2 mΩ)	3216 (1206)	1.90±0.20	3.50±0.20	8.00±0.30	3.50±0.10						1.40±0.20	—
ERJMP2 (3~50 mΩ)	3216 (1206)										1.10±0.20	_
ERJMP3 (1 ~2 mΩ)	5025 (2010)	0.00.0.00	F 40:0.00	12.00	5 50:0 40	1.75	4.00	2.00	4.00	1.50	1.55±0.20	_
ERJMP3 (3~50 mΩ)	5025 (2010)	2.90±0.20	5.40±0.20	±0.30	5.50±0.10	±0.10	±0.10	±0.05	±0.10	+0.10/0	1.15±0.20	_
ERJMP4 (1 ~2 mΩ)	6432 (2512)			10.00							1.60±0.20	1.5 min.
ERJMP4 (3~50 mΩ)	6432 (2512)	3.50±0.20	6.90±0.20	12.00 ±0.30	5.50±0.10						1.20±0.20	_
ERJM1W	6432 (2512)	1									1.80±0.20	1.5 min.

Embossed carrier taping (8 mm Pitch)

			uping										
Current sensing resistors, Metal plate type								Unit : mm					
	Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т	øD ₁
	ERJMS6	6468 (2526)	6.90±0.20	7.50±0.20	12.00	5.50±0.05	1.75	8.00	2.00	4.00	1.50	2.45±0.20	1.5 min.
	LINIMOO	0400 (2020)	0.3010.20	1.3010.20	±0.30	0.0010.00	±0.10	±0.10	±0.05	±0.10	+0.10/0	2.4010.20	1.5 mm.

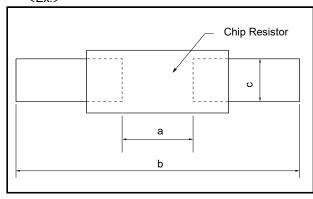
[^]82

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Should a safety concern arise regarding this product, please be sure to contact us immediately.

Recommended land pattern

- An example of a land pattern for the rectangular type is shown below.
- <Ex.>



High power (double-sided resistive elements structure) type

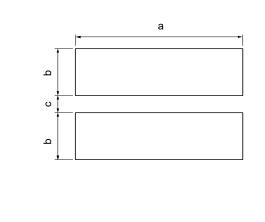
Part No.	Size	Dimensions		
Tarrio.	(inch)	a b		С
ERJ2LW/2BW	1005 (0402)	0.52	1.4 to 1.6	0.4 to 0.6
ERJ3LW/3BW	1608 (0603)	0.5 to 0.8	2.5 to 2.7	0.9 to 1.1
ERJ6LW		0.6 to 0.8	3.2 to 3.8	1.1 to 1.4
ERJ6BW		0.9	3.2 to 3.8	1.1 to 1.4
ERJ6CW	2012	0.7 to 0.9	3.2 to 3.8	1.1 to 1.4
(10 to 13 mΩ)	(0805)	0.7 10 0.9	3.2 10 3.0	1.1 10 1.4
ERJ6CW		0.9 to 1.1	2 0 to 2 0	1.1 to 1.4
(15 to 30 mΩ)		0.9 10 1.1	3.2 to 3.8	1.1 10 1.4
ERJ8BW				
ERJ8CW]	1.2	4.4 to 5.0	1.3 to 1.8
(10 to 16 mΩ)	3216 (1206)			
ERJ8CW	(1200)	2.0.to 2.0	1 1 to 5 0	1 0 to 1 0
(18 to 50 mΩ)		2.0 to 2.6	4.4 to 5.0	1.2 to 1.8
				Unit : mn

High temperature type (ERJH) High precision type (ERA) Current sensing type (ERJ*L/B/C, ERJ*R, ERJL) Small & high power type (ERJP, ERJT) Anti-sulfurated type (ERJS, ERJU) General purpose type (ERJ)

	Dimensions				
а	b	с			
0.15 to 0.20	0.5 to 0.7	0.20 to 0.25			
0.3 to 0.4	0.8 to 0.9	0.25 to 0.35			
0.5 to 0.6	1.4 to 1.6	0.4 to 0.6			
0.7 to 0.9	2.0 to 2.2	0.8 to 1.0			
1.0 to 1.4	3.2 to 3.8	0.9 to 1.4			
2.0 to 2.4	4.4 to 5.0	1.2 to 1.8			
2.0 to 2.4	4.4 to 5.0	1.8 to 2.8			
3.3 to 3.7	5.7 to 6.5	2.3 to 3.5			
3.6 to 4.0	6.2 to 7.0	1.8 to 2.8			
5.0 to 5.4	7.6 to 8.6	2.3 to 3.5			
3.6 to 4.0	7.6 to 8.6	2.3 to 3.5			
	0.15 to 0.20 0.3 to 0.4 0.5 to 0.6 0.7 to 0.9 1.0 to 1.4 2.0 to 2.4 2.0 to 2.4 3.3 to 3.7 3.6 to 4.0 5.0 to 5.4	0.15 to 0.20 0.5 to 0.7 0.3 to 0.4 0.8 to 0.9 0.5 to 0.6 1.4 to 1.6 0.7 to 0.9 2.0 to 2.2 1.0 to 1.4 3.2 to 3.8 2.0 to 2.4 4.4 to 5.0 2.0 to 2.4 4.4 to 5.0 3.3 to 3.7 5.7 to 6.5 3.6 to 4.0 6.2 to 7.0 5.0 to 5.4 7.6 to 8.6			

* ERJL1W

• An example of a land pattern for high power chip resistors / Wide terminal type is shown below.



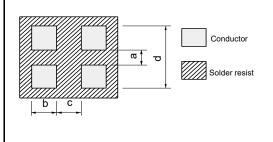
			Unit : mm		
Part No.	Dimensions				
Fait NO.	а	b	С		
ERJA1	6.4	1.70	0.60		
ERJB1					
ERJC1 ^{*1}	5.0	1.30	0.75		
ERJD1 ^{*2}					
ERJB2	3.2	0.95	0.70		
ERJD2 ^{*2}	5.2	0.95	0.70		
ERJB3	2.0	0.80	0.60		

*1: Anti-Sulfurated High power chip resistors / Wide terminal type

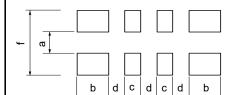
*2: Low TCR High power chip resistors / Wide terminal type

Recommended land pattern

• An example of a land pattern for Chip Resistor Array, Anti-Sulfurated Chip Resistor Array and Chip Attenuator is shown below. Unit : mm

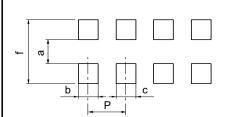


Part No.	Dimensions				
Fait NO.	а	b	С	d	
EXB14V EXB14A	0.30	0.30	0.30	0.80 to 0.90	
EXB24V EXBU24 EXB24A	0.5	0.35 to 0.40	0.30	1.4 to 1.5	

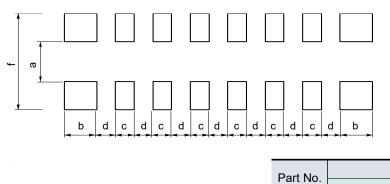


					Unit : mm	
Part No.	Dimensions					
Part NO.	а	b	С	d	f	
EXB28V EXBU28	0.40	0.525	0.25	0.25	1.40	
EXBN8V	0.45 to 0.50	0.35 to 0.38	0.25	0.25	1.40 to 2.00	

Unit : mm



					01111 . 11111		
Davit Nia							
Part No.	а	b	С	f	Р		
EXB18V	0.20 to 0.30	0.15 to 0.20	0.15 to 0.20	0.80 to 0.90	0.40		
EXBV4V EXBV8V	0.7 to 0.9	0.4 to 0.45	0.4 to 0.45	2 to 2.4	0.80		
EXB34V EXB38V EXBU34 EXBU38	0.7 to 0.9	0.4 to 0.5	0.4 to 0.5	2.2 to 2.6	0.80		
EXBS8V	1 to 1.2	0.5 to 0.75	0.5 to 0.75	3.2 to 3.8	1.27		



				Unit : mm			
	Dimensions						
а	b	С	d	f			
1.00	0.425	0.25	0.25	2.00			

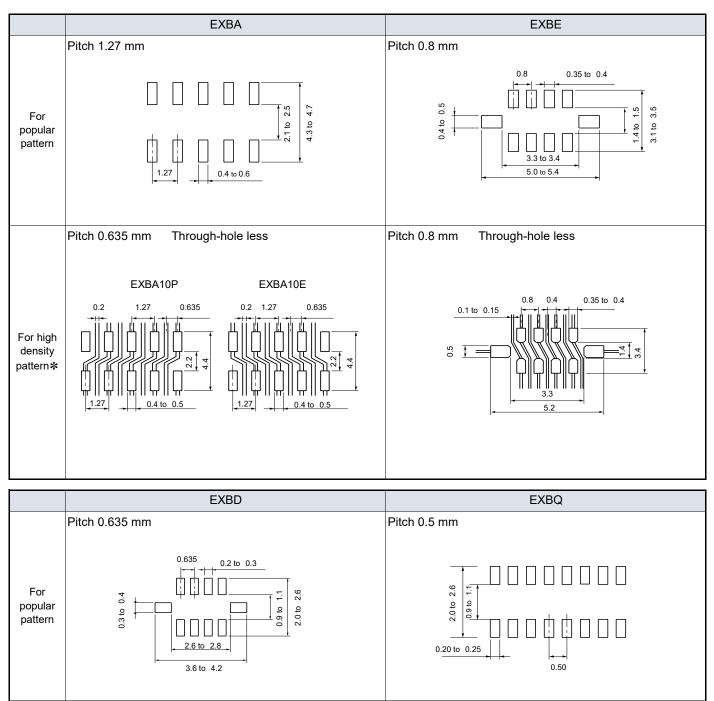
Design and specifications are each subject to charge winnout nouser, i.e., see ..., Should a safety concern arise regarding this product, please be sure to contact us immediately. 84 Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

EXB2HV

EXBU2H

Recommended land pattern

• An example of a land pattern for Chip Resistor Networks is shown below.

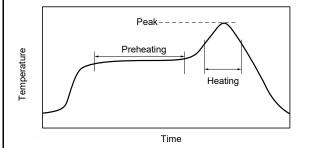


* When designing high density land patterns, examine the reliability of isolation among the lines and adopt the chip resistor networks.

Recommended soldering conditions (Rectagular type)

Recommendations and precautions are described below.

- Recommended soldering conditions for reflow
 Reflow soldering shall be performed a maximum of two times.
 - Please contact us for additional information when used in conditions other than those specified.
 - •Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



_	For soldering (Example : Sn/Pb)				
		Temperature	Time		
	Preheating	140 ℃ to 160 ℃	60 s to 120 s		
-	Main heating	Above 200 ℃	30 s to 40 s		
	Peak	235 ± 5 ℃	max. 10 s		

For lead-free soldering (Example : Sn/Ag/Cu)

	Temperature	Time
Preheating	150 ℃ to 180 ℃	60 s to 120 s
Main heating	Above 230 ℃	30 s to 40 s
Peak	max. 260 ℃	max. 10 s

• Recommended soldering conditions for flow

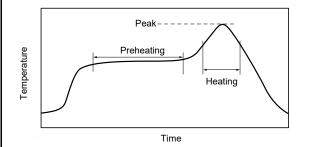
	For soldering		For lead-free soldering	
	Temperature	Time	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s	150 ℃ to 180 ℃	60 s to 120 s
Soldering	245 ± 5 ℃	20 s to 30 s	max. 260 ℃	max. 10 s

Recommended soldering conditions (Chip resistor array / networks and Chip attenuator)

Recommendations and precautions are described below.

Recommended soldering conditions for reflow

- •Reflow soldering shall be performed a maximum of two times.
- •Please contact us for additional information when used in conditions other than those specified.
- Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



For soldering (Example : Sn/Pb)

	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s
Main heating	Above 200 ℃	30 s to 40 s
Peak	235 ± 5 ℃	max. 10 s

For lead-free soldering (Example : Sn/Ag/Cu)

	Temperature	Time
Preheating	150 ℃ to 180 ℃	60 s to 120 s
Main heating	Above 230 ℃	30 s to 40 s
Peak	max. 260 ℃	max. 10 s

Flow soldering

We do not recommend flow soldering, because a solder bridge may form. Please contact us regarding flow sol der ing of EXBA series.

Standard for resistance value and resistance tolerance

Basis standard

IEC Publication	n 60062	: Marking codes for resistors and capacitors.
IEC Publication	n 60063	: Preferred number series forresistors and capacitors.
JIS C 5062	: Marking co	odes for resistors and capacitors.
JIS C 5063	: Preferred r	number series for resistors and capacitors.

Resistance values

The resistance values are notched by "Ratio" below in each series.

Series	Resistance tolerance (Standard)	Ratio	Remarks
E6	±20 %	⁶ √10=1.46	
E12	±10 %	¹² √10=1.21	
E24	± 5 %	²⁴ √10=1.10	Please refer to standard resistance values shown on this catalog.
E48	± 2 %	⁴⁸ √10=1.05	
E96	± 1%	⁹⁶ √10=1.02	

How to express the resistance value with a Panasonic part number

The resistance value expressed in ohms is iden tified by a three digit number or a four digit number.

The last digit specifies the number of zeroes to follow.

The letter "R" shall be used as the decimal point for less than 10 $\Omega.$

The examples of a three digit number

Resistance code	Value in ohms (Ω)
R56	0.56
5R6	5.6
100	10
271	270
102	1 k
273	27 k
104	100 k
275	2.7 M
106	10 M
107	100 M

The examples of a four digit number

Resistance code	Value in ohms (Ω)
R562	0.562
5R62	5.62
56R2	56.2
1000	100
2711	2.71 k
1002	10 k
2713	271 k
1004	1 M
2751	2.71 M
1006	100 M

How to express the resistance tolerance with a Panasonic part number

The resistance tolerance is identified by a single letter in accordance with the following table and the code is placed just before the resistance code in the following examples.

Tolerance code	Tolerance (%)	Examples
W	± 0.05	W1001 : 1000 Ω ± 0.05 %
В	± 0.1	B1001 : 1000 Ω ± 0.1 %
С	± 0.25	C1001 : 1000 Ω ± 0.25 %
D	± 0.5	D1001 : 1000 Ω ± 0.5 %
F	± 1	F1001 : 1000 Ω ± 1 %
G	± 2	G1001 : 1000 Ω ± 2 %
J	± 5	J101 : 100 Ω ± 5 %
К	± 10	K101 : 100 Ω ± 10 %
М	± 20	M101 : 100 Ω ± 20 %

Standard resistance values

$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	
$ 10 \\ 10 \\ 10 \\ 10 \\ 10 \\ 10 \\ 11 \\ 11 \\ 11 \\ $	
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	
10 11 110	
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	4.2
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	10
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	
143 30 309 6 147 147 316 681	
147 681 681	
15 154 332 715 154 332 715	
154 158 33 340 68 7	
15 162 33 348 750 750	
169 169 365 787 169 36 365	
174 68 8	
15 178 33 383 383 825	15
18 187 39 402 866 8	
191 412 82 8	
18 196 39 422 196 422 909	
200 432 9	
20 205 43 442 9	
205 442 953 210 453 9	

Safty Precautions

When using our products, no matter what sort of equipment they might be used for, be sure to confirm the applications and environmental conditions with our specifications in advance.



Panasonic Industry Co., Ltd. Device Solutions Business Division

1006 Kadoma, Kadoma City, Osaka 571-8506 Japan

© Panasonic Industry

Unauthorized duplication of this catalog is strictly forbidden. The contents of catalog are as of May 2024.